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# <sup>1</sup> C<sub>3</sub>N<sub>5</sub>: A Low Bandgap Semiconductor Containing an Azo-Linked <sup>2</sup> Carbon Nitride Framework for Photocatalytic, Photovoltaic and <sup>3</sup> Adsorbent Applications

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## 10 Supporting Information

ABSTRACT: Modification of carbon nitride based polymeric 11 2D materials for tailoring their optical, electronic and 12 chemical properties for various applications has gained 13 significant interest. The present report demonstrates the 14 synthesis of a novel modified carbon nitride framework with a 15 remarkable 3:5 C:N stoichiometry  $(C_3N_5)$  and an electronic 16 bandgap of 1.76 eV, by thermal deammoniation of melem 17 hydrazine precursor. Characterization revealed that in C<sub>3</sub>N<sub>5</sub> 18 polymer, two s-heptazine units are bridged together with azo 19 20 linkage, which constitutes an entirely new and different bonding fashion from  $g-C_3N_4$  where three heptazine units are 21 linked together with tertiary nitrogen. Extended conjugation 22 due to overlap of azo nitrogens and increased electron density 23



on heptazine nucleus due to the aromatic  $\pi$  network of heptazine units lead to an upward shift of the valence band maximum 24 resulting in bandgap reduction down to 1.76 eV. XRD, He-ion imaging, HR-TEM, EELS, PL, fluorescence lifetime imaging, 25 Raman, FTIR, TGA, KPFM etc. clearly show that the properties of  $C_3N_5$  are distinct from pristine carbon nitride (g- $C_3N_4$ ). 26 When used as an electron transport layer (ETL) in MAPbBr<sub>3</sub> based halide perovskite solar cells,  $C_3N_5$  outperformed g- $C_3N_4$ , in 27 particular generating an open circuit photovoltage as high as 1.3 V, while C3N5 blended with MAxFA1-xPb(I0.85Br0.15)3 28 perovskite active layer achieved a photoconversion efficiency (PCE) up to 16.7%.  $C_3N_5$  was also shown to be an effective visible 29 light sensitizer for  $TiO_2$  photoanodes in photoelectrochemical water splitting. Because of its electron-rich character, the  $C_3N_5$ 30 material displayed instantaneous adsorption of methylene blue from aqueous solution reaching complete equilibrium within 10 31 min, which is significantly faster than pristine  $g-C_3N_4$  and other carbon based materials.  $C_3N_5$  coupled with plasmonic silver 32 nanocubes promotes plasmon-exciton coinduced surface catalytic reactions reaching completion at much low laser intensity (1.0 33 mW) than g-C<sub>3</sub>N<sub>4</sub>, which showed sluggish performance even at high laser power (10.0 mW). The relatively narrow bandgap 34 and 2D structure of C<sub>3</sub>N<sub>5</sub> make it an interesting air-stable and temperature-resistant semiconductor for optoelectronic 35 36 applications while its electron-rich character and intrasheet cavity make it an attractive supramolecular adsorbent for environmental applications. 37

## 38 INTRODUCTION

<sup>39</sup> The last few decades have witnessed the rise of semi-<sup>40</sup> conducting, all-organic polymers as excellent metal-free and <sup>41</sup> visible light-active materials for various optoelectronic and <sup>42</sup> energy harvesting applications.<sup>1</sup> Although impressive improve-<sup>43</sup> ments in performance have been achieved, particularly for <sup>44</sup> plastic solar cells, the synthesis procedures for semiconducting <sup>45</sup> polymers are cumbersome and difficult to scale up,<sup>2</sup> and the <sup>46</sup> organic semiconductors themselves are unstable under the <sup>47</sup> action of heat, light and/or ambient air.<sup>3</sup> Consequently, there <sup>48</sup> are scalability concerns related to semiconducting polymers,<sup>4</sup> and requirement of heavy encapsulation to achieve even <sup>49</sup> modest durability in the photovoltaic application. The same <sup>50</sup> concerns, related to oxidative stability and durability, have also <sup>51</sup> ruled out the use of semiconducting polymers in photocatalytic <sup>52</sup> applications. <sup>53</sup>

A very different approach toward forming and exploiting all- $_{54}$  organic, polymeric semiconductors in optoelectronic and  $_{55}$  energy harvesting applications consists of using doped and  $_{56}$ 

Received: January 5, 2019 Published: February 14, 2019 57 substituted graphenic frameworks as building blocks to achieve 58 two-dimensional (2D) semiconductors with well-defined 59 bandgaps and structural motifs.<sup>5,5,6</sup> The major advantages of 60 graphenic semiconductors are their chemical robustness and 61 the simplicity of synthesis. Several graphenic semiconductors 62 are synthesizable using solvothermal synthesis and/or solid-63 state reactions, and graphenic semiconductors are perfectly 64 stable in ambient conditions up to temperatures of several 65 hundred degrees Celsius. As a result of this exceptional 66 stability, almost no structural or chemical degradation of 67 photocatalytic action is observed even after several reuse 68 cycles.<sup>7</sup>

Among graphenic semiconductors, graphitic carbon nitride 69 70 (g-C<sub>3</sub>N<sub>4</sub>), composed of tris-s-triazine (s-heptazine, C<sub>6</sub>N<sub>7</sub>) units 71 bridged together with nitrogen atoms to give a 2D graphitic 72 structure has gained significant interest due to its astonishing 73 electronic, optical and physicochemical properties.<sup>8</sup> Continu-74 ous repetition of the heptazine motif leads to a bandgap of 2.7 75 eV with band edge positions ( $E_{CB}$ , -1.1 eV and  $E_{VB}$ , +1.6 eV) 76 that render it compatible with sunlight-driven water splitting, 77 CO<sub>2</sub> photoreduction and the photooxidation of a number of 78 organic compounds.<sup>9</sup> Further, the plentiful presence of 79 electron-rich sites and basic nitrogens in the g-C<sub>3</sub>N<sub>4</sub> scaffold 80 enables the promotion of various catalytic reactions, i.e. 81 alkylation, esterification, oxidation, etc. and pollutant removal s2 (dye adsorption).<sup>6a,10</sup> The somewhat wide bandgap of  $g-C_3N_4$ 83 means that it can absorb only the ultraviolet and blue fraction <sup>84</sup> of solar spectrum ( $\lambda$  < 450 nm), which limits its performance 85 in photocatalytic and photovoltaic applications. Doping with 86 various heteroatoms such as P, F, B and S has been utilized to 87 improve the visible light absorption profile and photo- $_{88}$  efficiency.<sup>11</sup> Like all semiconductors, g-C<sub>3</sub>N<sub>4</sub> suffers the innate 89 drawback of carrier recombination detrimental to catalytic and 90 photocatalytic processes. Many surface modification ap-91 proaches such as increasing the surface area via soft and 92 hard templating, using two or more precursors, transformation 93 of bulk material into sheets, doping with metals (Ag, Cu, Rh, 94 Pt, Na, etc.) and metal oxides  $(CoO_x)$  for electron and hole 95 capture, coupling with other semiconductors/metal complexes 96 to form heterojunctions, and blending with graphene have 97 been employed to improve the photocatalytic and catalytic 98 performance of g-C<sub>3</sub>N<sub>4</sub>.<sup>12</sup> However, less attention has been 99 paid to chemical structure modification, which can lead to the 100 generation of a more robust, band edge tuned g-C<sub>3</sub>N<sub>4</sub> 101 framework with entirely new physicochemical properties for 102 efficient catalytic/photocatalytic applications. It has been 103 found that addition of extra nitrogen-rich moieties in the g-104 C<sub>3</sub>N<sub>4</sub> scaffold to increase the N:C ratio from 4:3 ratio in CN 105 can reduce the bandgap significantly, due to a more extended 106 conjugated network and the participation of the lone pair on 107 the N atom with the  $\pi$  conjugated system of heptazine motif. 108 Vinu et al. demonstrated the synthesis of N-rich carbon nitride 109 (MCN-8) using 3-amino-1,2,4-triazole to afford C<sub>3</sub>N<sub>5</sub> 110 stoichiometry resulting in a significant decrease in bandgap 111 (2.2 eV) due to extended conjugation.<sup>13</sup> However, this 112 increase in N:C ratio to 5:3 (from the 4:3 ratio in  $g-C_3N_4$ ) 113 was due to the presence of the N-rich 1,2,4-triazole moiety 114 linked to the heptazine motif and not because of the direct 115 incorporation of the extra N atom in the heptazine nucleus. 116 The same group has also reported the synthesis of mono/and 117 diamino-s-tetrazine based carbon nitride materials (i.e., MCN-118 ATN, MCN-4 and MCN-9) with C<sub>3</sub>N<sub>5</sub> to C<sub>3</sub>N<sub>6</sub> stoichiometry 119 using 3-amino-1,2,4-triazine/aminoguanidine hydrochloride

precursor and SBA-15/KIT-6 templating material.<sup>14</sup> The N- 120 rich 1,2,4-triazine or 1,2,4,5-tetrazine moieties were bridged 121 together with tertiary nitrogen in a similar fashion to triazine 122 based carbon nitride and a significant decrease in band gap was 123 observed due to the addition of extra nitrogens. In a recent 124 report, mesoporous triazole and triazine framework modified 125 carbon nitride materials with C3N4.8 empirical formula 126 synthesized by using 5-amino-1H-tetrazole (5-ATTZ) pre- 127 cursor and their hybrid with graphene displayed excellent 128 performance in the oxygen reduction reaction.<sup>15</sup> Fang et al. 129 reported the synthesis of nitrogen self-doped graphitic carbon 130 nitride  $(C_3N_{4+x})$  by heating hydrazine treated melamine in a 131 sealed ampule. In  $C_3N_{4+x}$  the excess N atoms replace terminal 132 C atoms in the heptazine nucleus and the excess charge on the 133 N atom gets redistributed leading to electron-rich heptazine 134 motifs due to which C<sub>3</sub>N<sub>4+x</sub> possessed a narrower bandgap 135 (2.65 eV) with concomitant shifts in the conduction and 136 valence band edge positions ( $E_{\rm CB}$ , -0.98 eV and  $E_{\rm VB}$ , +1.67 137 eV).<sup>16</sup> In these N-rich carbon nitrides, the N-rich triazine or 138 heptazine based unit remains linked together with tertiary 139 nitrogen, N(C)<sub>3</sub> and increased stochiometric N:C ratio was 140 due to the replacement of C via N in triazine or heptazine ring 141 system. Similarly, carbon-rich C<sub>3</sub>N<sub>4</sub> network also facilitates 142 bandgap narrowing and efficient charge separation due to the 143 extended conjugated network. Zhang et al. reported the 144 hydrothermal synthesis of low bandgap, C-rich C<sub>3</sub>N<sub>4</sub> materials 145 with extended conjugated networks using melamine (as 146 heptazine ring source) and glucose (as carbon source) 147 precursors.<sup>12c,17</sup> However, the use of melamine and other C 148 and N sources can afford only C<sub>3</sub>N<sub>4</sub> structures possessing 149 randomly distributed domains within the C<sub>3</sub>N<sub>4</sub> framework due 150 to the uncontrolled reaction and these regions work as trap 151 centers. Melem (2,5,8-triamino-s-heptazine) considered the 152 smallest monomeric unit of g-C<sub>3</sub>N<sub>4</sub> framework, provides the 153 opportunity to manipulate chemical structure by incorporating 154 other units in the  $C_3N_4$  framework in a more controlled 155 fashion.<sup>16-18</sup> Shiraishi et al. reported the synthesis of modified 156 CN-polydiimide framework  $(g-C_3N_4/PDI_x)$  by solid-state 157 reaction between melem and electron deficient pyromellitic 158 dianhydride (PMDA) and demonstrated that the band edge 159 positions of  $g-C_3N_4/PDI_x$  could be tuned by limiting the 160 number of PDI units in the framework.<sup>19</sup> Heterostructured 161  $(C_{ring}-C_3N_4)$  embodiments of conductive, in-plane,  $\pi$  con- 162 jugated carbon rings incorporated in the C<sub>3</sub>N<sub>4</sub> matrix were 163 prepared by thermal dehydrogenation reaction between 164 glucose and melem, and the obtained  $C_{\rm ring}\text{-}C_3N_4$  hetero-  $_{165}$ structure achieved fast spatial charge transfer from g- $C_3N_4$  to 166  $C_{ring}$  motif facilitating efficient water splitting.<sup>18</sup>d,<sup>20</sup> The 167 replacement of amino functionalities on melem/melamine by 168 nitrogen-rich functionalities, i.e. azide  $(-N_3)$ , expedited the 169 synthesis of N-rich carbon nitride, i.e. 2,5,8-triazido-s- 170 heptazine,  $(C_6N_7)(N_3)_3$ , which after thermal heating, afforded 171 N-rich carbon nitride.<sup>20,21</sup> Likewise, triazine containing N-rich 172 CN was also synthesized by thermal annealing of 2,4,6- 173 triazido-1,3,5-triazine [cyanuric triazide,  $(C_3N_3)(N_3)_3$ ].<sup>20,22</sup> 174 However, the synthesis procedure involved sodium azide and 175 concomitant shock sensitive explosion hazards; furthermore, 176 azide intermediates are highly undesirable.

Herein, we demonstrated the synthesis of novel modified 178 carbon nitride framework with a  $C_3N_5$  stoichiometry by 179 thermal deammoniation of 2,5,8-trihydrazino-s-heptazine, also 180 known as melem hydrazine (MH), as a safe and environ-181 mentally benign precursor (Figure 1). The obtained carbon 182 fi



Figure 1. Chemical structure of g-C<sub>3</sub>N<sub>4</sub> and carbon nitride modified C<sub>3</sub>N<sub>5</sub> framework.



Figure 2. Synthesis schematic of  $C_3N_5$  from melem via melem hydrazine (Atom color: N - blue, C - gray and H - white). The vials show the distinct color of the reaction product contrasted with that of the precursor.

183 nitride modified framework was denoted as C<sub>3</sub>N<sub>5</sub> due to its 3:5 184 C:N stoichiometric ratio. Characterization studies revealed 185 that the C<sub>3</sub>N<sub>5</sub> framework contains heptazine moieties bridged 186 together by azo linkage (-N=N-). The presence of azo 187 linkage extends the  $\pi$  conjugated network due to overlap 188 between the p orbitals on N atoms constituting the azo bond 189 and  $\pi$  system of heptazine motif, which resulted in the 190 reduction of the electronic bandgap to 1.76 eV. C<sub>3</sub>N<sub>5</sub> displayed 191 improved photosensitization properties at longer wavelengths 192 for solar water splitting. Further, because of the increased 193 electron charge density on the ring nitrogen, C<sub>3</sub>N<sub>5</sub> exhibited 194 instantaneous adsorption of methylene blue from aqueous 195 solution. Solar cell devices fabricated using low bandgap  $C_3N_{51}$ 196 as an electron transporting layer (ETL) in MAPbBr<sub>3</sub> based 197 perovskite solar cells demonstrated improved power con-198 version efficiency (PCE), open circuit voltage  $(V_{oc})$  etc. 199 compared to solar cells made from g-C<sub>3</sub>N<sub>4</sub> based ETL due to 200 tuned band alignment. Blending a small amount of  $C_3N_5$  (4.0 201 wt %) with MA<sub>x</sub>FA<sub>1-x</sub>Pb $(I_{0.85}Br_{0.15})_3$  perovskite active layer led 202 to an increase in PCE up to 16.68% with  $V_{\rm oc}$  of 1.065 V and  $J_{\rm sc}$ 

of 22.87 mA/cm<sup>2</sup> higher than conventional and  $g-C_3N_4$  <sup>203</sup> blended solar cell architectures. Compared to  $g-C_3N_4$ ,  $C_3N_5$  <sup>204</sup> exhibited a remarkably enhanced performance in the plasmon- <sup>205</sup> exciton codriven photoreduction of 4-nitrobenezenethiol to <sup>206</sup> 4,4'-dimercaptoazobenzene. <sup>207</sup>

## RESULTS AND DISCUSSION

Melem (2,5,8-triamino-s-heptazine) served as the precursor 209 monomeric unit for the synthesis of  $C_3N_5$  polymer. Melem was 210 synthesized by heating melamine at 425 °C overnight followed 211 by purification in boiling water. The obtained melem was 212 treated with hydrazine hydrate (NH<sub>2</sub>NH<sub>2</sub>·H<sub>2</sub>O, 55% in water) 213 in an autoclave at 140 °C for 24 h. The treatment of melem 214 with hydrazine hydrate transformed amino ( $-NH_2$ ) function- 215 alities into hydrazino ( $-NH-NH_2$ ) functionalities, which 216 afforded melem hydrazine, MH (2,5,8-trihydrazino-s-hepta- 217 zine).<sup>23</sup> The obtained white melem hydrazine was subjected to 218 programmed heating at 450 °C for 2 h to obtain orange 219 colored  $C_3N_5$  polymer (Figure 2) (see Supporting Information 220 f2 for experimental details). Melem hydrazine has a highly 221

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222 hydrogen bonded structure which facilitates the formation of 223 an azo-bridged heptazine framework by thermal condensation. 224 Previously, Gillan also reported the formation of similar azo-225 bridged functionalities by heating nitrogen-rich 2,4,6-cyanuric 226 triazide or triazido-1,3,5-triazine  $(C_3N_3)(N_3)_3$  to form differ-227 ential composition triazine based carbon nitride.<sup>22,24</sup> In the 228 same report, Gillan suggested that transformation of cyanuric 229 triazide into azo-bridged triazine carbon nitride framework 230 proceeded through the nitrene intermediate  $(C_3(N_3)_2N:)$  and 231 that the formation of  $C_3N_5$  from melem hydrazine might 232 proceed via a similar intermediate due to the thermolabile 233 nature of hydrazine functionalities. The structures of melem, 234 melem hydrazine and hydrogen bonded melem hydrazine are 235 given in Supporting Information (Figure S1).

<sup>236</sup> The surface morphology of the  $C_3N_5$  polymer was <sup>237</sup> investigated using a He-ion microscope equipped with an <sup>238</sup> electron flood gun to facilitate positive charge neutralization <sup>239</sup> accumulated from the He-ion beam (Figure 3a). The He-ion



**Figure 3.** (a) He-ion image of  $C_3N_5$ , and HR-TEM images of  $C_3N_5$  (b) at 50 nm, (c) at 10 nm and (d) at 5 nm scale bar; left and right insets showing SAED diffraction pattern and interplanar *d* spacing, respectively.

240 images of MHP show a rough, crumpled graphenic scaffold 241 with some erupted morphologies, which indicate that the high 242 temperature treatment of MH monomeric unit facilitated 243 polymerization into an irregular sheet-like structure. The fine 244 structure of C<sub>3</sub>N<sub>5</sub> material was determined using high 245 resolution transmission electron microscopy (HR-TEM) 246 (Figure 3b-d). The carbon nitride like layered sheet 247 architecture is clearly evident in the TEM image of  $C_3N_5$  at 248 50 nm scale bar (Figure 3b). Under long duration exposure of 249 the electron beam, C<sub>3</sub>N<sub>5</sub> starts to degrade and shrink which  $_{250}$  likely resulted due to high energy electrons breaking the -N=251 N- linkage. HR-TEM images at 10 and 5 nm scale bar show 252 crystallite fringes of nanoporous multilayered sheets with an 253 interplanar d-spacing of 0.32 nm, corresponding to the 002 254 plane of the graphitic structure (Figure 3c,d, and inset). The 255 observed d-spacing in C<sub>3</sub>N<sub>5</sub> was identical to g-C<sub>3</sub>N<sub>4</sub> from

which we infer that during the thermal polymerization step, the 256 stacking pattern of sheets in  $C_3N_5$  remains similar to that in 257 bulk g- $C_3N_4$ . The broad, less intense ring in the selected area 258 electron diffraction (SAED) pattern was attributed due to 259 diffraction of electrons by the 002 plane; however, the low 260 intensity of the ring suggests amorphous nature of the material 261 (inset of Figure 3d).

The surface chemical composition of the synthesized 263 material was investigated using X-ray photoelectron spectros- 264 copy, XPS (Figure 4). The XPS elemental survey scan of  $C_3N_5$  265 f4 shows peaks corresponding to C 1s, N 1s, Na 1s, Cl 2p and O 266 1s (Figure S2a). The presence of Na 1s and Cl 2p is due to 267 intercalated Na<sup>+</sup> ions in the supramolecular cavity of the 268 polymeric motif (Figure 1) and the residual NaCl formed 269 during the purification step of MH. After excluding Na 1s, Cl 270 2p and O 1s peaks, the at. % values of C and N in the C<sub>3</sub>N<sub>5</sub> 271 were found to be 36.76% and 63.24% respectively, which 272 represent an empirical formula of C3N5.16 for the C3N5 273 polymer (Table 1). The obtained composition matched well 274 tl with theoretical C<sub>3</sub>N<sub>5</sub> (N - 62.50 at. %, and C - 37.50 at. %) 275 stoichiometric carbon nitride materials. The high resolution 276 XPS spectrum of C<sub>3</sub>N<sub>5</sub> in C 1s region was deconvolved into 277 two peak components at binding energies of 284.8 and 287.9 278 eV corresponding to the presence of sp<sup>3</sup> and sp<sup>2</sup> hybridized 279 carbons, respectively (Figure 4a). The sp<sup>3</sup> carbon peak 280 originated from adventitious carbons, edge group carbons 281 and turbostratic carbons present in the scaffold of C3N5 282 polymer while the relatively stronger sp<sup>2</sup> peak appeared due 283 to N=C-N type aromatic carbons, which constitute the <sup>284</sup> carbon nitride-like framework of  $C_3N_5$ .<sup>25</sup> The core level HR- <sup>285</sup> 285 XPS in N 1s after deconvolution gave two peak components 286 located at 398.7 and 400.2 eV. The peak at a binding energy of 287 398.7 eV was assigned to tertiary  $N-(C)_3$  and secondary C= 288 N-C nitrogens present in the aromatic ring structure while 289 another peak at 400.2 eV was due to the presence of primary 290 residual -NH2 and bridging C-N=N-C type nitrogens 291 (Figure 4b).<sup>25,26</sup> From the N 1s XPS spectrum, the at. % of N 292 present in aromatic ring  $(N_{\rm ring})$  and bridging  $(N_{\rm bridging})$  were 293 found to 60.47% and 39.53% respectively, and the at. % ratio 294 obtained was 3:2, which strongly supports the proposed 295 structure in which two heptazine units are interconnected with 296 the azo (-N=N-) motif and is also consistent with the 297 theoretical C<sub>3</sub>N<sub>5</sub> azo-linked structure (Table 1). Furthermore, 298 HR-XPS in Na 1s region gave a peak at 1071.9 eV due to the 299 presence of Na<sup>+</sup> ions in the polymeric skeleton and residual 300 NaCl (Figure S2b). The two peak components in Cl 2p XPS, 301 at binding energy values of 198.7 and 200.2 eV ascribed to Cl 302  $2p_{3/2}$  and Cl  $2p_{1/2}$  further validated the presence of Cl<sup>-</sup> in the 303 form of NaCl (Figure S2c). Two XPS peaks in the O 1s region 304 located at 531.6 and 532.4 eV were associated with surface 305 adsorbed adventitious oxygens and -OH groups (Figure S2d). 306 The nature of C and N bonding in g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> was 307 elucidated with electron energy loss spectroscopy (EELS) 308 (Figure 4c,d and Figure S3). The normalized EELS spectra of 309 g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> exhibited two major symmetric peaks due to 310 contribution of C-K and N-K edge loss. The C K-edges 311 signal of both g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> was composed of two peaks 312 located at located at 284.6 and 293.2 eV corroborated to 1s- $\pi^*$  313 and  $1s - \sigma^*$  electronic transition of sp<sup>2</sup> hybridized carbons 314 trigonally coordinated with nitrogens in s-heptazine nucleus 315 (Figure 4c).<sup>14a,b,27</sup> The relative intensity of  $\pi^*$  C K-edge signal 316 and  $\pi^*/\sigma^*$  peak area ratio of C<sub>3</sub>N<sub>5</sub> was higher than g-C<sub>3</sub>N<sub>4</sub> 317 suggesting increased conjugation in  $C_3N_5$  due to extended  $\pi$  318



Figure 4. Core level HR-XPS spectra of  $C_3N_5$  in (a) C 1s region, (b) N 1s region and normalized EELS spectra of g- $C_3N_4$  and  $C_3N_5$  showing relative intensity of  $\pi^*$  and  $\sigma^*$  peaks for (c) C K-edge and (d) N K-edge loss.

Table 1. (a	) Elemental A	nalysis of C <sub>3</sub> N	5 Showing C, I	H and N wt % a	nd Empirical Forn	nula and (ł	o) XPS Elemental .	Analysis of
C <sub>3</sub> N <sub>5</sub> Show	ving at. % and	Empirical Fo	rmula and Th	eir Comparison	with Theoretical	C <sub>3</sub> N <sub>5</sub> Con	nposition	

(a) elemental analysis								
serial. no.		N (wt %)	C (wt %)	H (wt %)	empirical formula	$N_{ m ring}$ : $N_{ m bridging}$ (at. % ratio)		
1	CHN analysis	61.27	31.81	2.68	$C_3N_{4.95}H_{1.01}$	_		
2	theoretical wt % value	66.02	33.98	-	$C_3N_5$	3:2 (60:40)		
(b) XPS elemental analysis								
serial. no.		N (at. %)	C (at. %)	H (at. %)	empirical formula	$N_{ m ring}$ : $N_{ m bridging}$ (at. % ratio)		
3	XPS analysis	63.24	36.76	-	C <sub>3</sub> N <sub>5.16</sub>	~3:2 (60.47:39.53)		
4	theoretical at. % value	62.50	37.50	-	$C_3N_5$	3:2 (60:40)		

319 orbitals overlap between bridging azo functionalities and 320 heptazine motifs.<sup>28</sup> The formation of extended  $\pi$  conjugated 321 network in C<sub>3</sub>N<sub>5</sub> was also supported by increased UV–vis 322 absorption profile and shorter TRPL lifetime decay (Figures 7 323 and 8). The N K-edges energy loss peaks for g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> 324 located at 399.8 and 408.5 eV, assigned to 1s- $\pi^*$  and 1s- $\sigma^*$ 325 electronic transition of sp<sup>2</sup> hybridized nitrogens in heptazine 326 ring and bridging N, further verify sp<sup>2</sup> hybridized nitrogen-rich 327 carbon nitride framework (Figure 4d).<sup>13</sup> Absence of any new 328 peak in N K-edge loss of C<sub>3</sub>N<sub>5</sub> demonstrate bridging nitrogens 329 in C<sub>3</sub>N<sub>5</sub> have almost identical electronic environment like 330 N(C)<sub>3</sub> nitrogens in g-C<sub>3</sub>N<sub>4</sub>.<sup>29</sup> The relative peak intensity of the 331 N K-edge  $\pi^*$  signal of C<sub>3</sub>N<sub>5</sub> was slightly lower than that of g-332 C<sub>3</sub>N<sub>4</sub>, demonstrating enhanced contribution of azo motifs in 333 1s- $\sigma^*$  transition. The replacement of tertiary bridging nitro-334 gens, N(C)<sub>3</sub> in g-C<sub>3</sub>N<sub>4</sub> via azo nitrogens, C—N=N-C, 335 renders a lone pair on azo nitrogens, which contributes to  $\sigma^*$ 

signal and relative intensity of  $\pi^*$  signal suppressed. However, 336 the total peak area of the N K-edge peak for C<sub>3</sub>N<sub>5</sub> was 337 increased, which demonstrated addition of extra nitrogens in 338 the carbon nitride framework. The N:C atomic ratio of C<sub>3</sub>N<sub>5</sub> 339 was calculated to be 1.62, which was in close agreement with 340 the theoretical value (1.66) and C:N value obtained from 341 CHNS analysis (1.65). Slightly lower N content might be due 342 to cleavage of azo bond resulting in loss of some nitrogens 343 under high energy electron beam. 344

To probe the proposed composition and structure of the 345 synthesized  $C_3N_5$  material, CHNS elemental analysis was 346 performed which gave 61.27 wt % N, 31.81 wt % C and 2.68 347 wt % H suggesting an empirical formula of  $C_3N_{4.95}H_{1.01}$  which 348 was in close proximity with the theoretical wt % for  $C_3N_5$  349 composition (Table 1). Slight difference between predicted 350 and observed C:N ratio might be due to the presence of 351 unbonded  $-NH_2$  at the edge of sheets, formed by cleavage of 352



Figure 5. CPMAS NMR spectra (a)  ${}^{13}C$  of MH, (b)  ${}^{13}C$  of  $C_3N_{5'}$  (c)  ${}^{15}N$  of MH and (d)  ${}^{15}N$  of  $C_3N_5$ .



Figure 6. FTIR spectra of (a) melem, (b) melem hydrazine, (c)  $g-C_3N_4$ , (d)  $C_3N_5$ , and XRD diffraction pattern of (e) melem, (f) melem hydrazine, (g)  $g-C_3N_4$ , (h)  $C_3N_5$ .

353 hydrazino group  $(-NH-NH_2)$  at elevated temperature and 354 loss of some azo nitrogens.<sup>9b,10b</sup> As expected, sulfur was not 355 present at measurable levels. Notably, the observed hydrogen 356 might arise from  $-NH_2$  and -OH groups present at the edge 357 of the polymeric framework.

To elucidate the chemical structure of MH and C<sub>3</sub>N<sub>5</sub> 358 359 materials, solid-state nuclear magnetic resonance (NMR) spectroscopy using the cross-polarization magic-angle spinning 360 (CPMAS) technique was performed (Figure 5). CPMAS 361 NMR enables the structural investigation of local- and 362 363 medium-range structure in micro- and nanocrystalline compounds. The <sup>13</sup>C CPMAS NMR spectra of melem 364 365 hydrazine (MH) display three NMR signals at 164, 160 and 366 154 ppm (Figure 5a). The <sup>13</sup>C NMR signals at 164 and 160 367 ppm originated from N<sub>2</sub>C-NHNH<sub>2</sub> carbons while the 368 resonance at 154 ppm was observed from CN<sub>3</sub> carbons of 369 the heptazine nucleus. The observed signals were in good 370 agreement with the reported NMR spectra for MH and melem

f5

based structures.<sup>18a,24,30</sup> The CPMAS NMR spectrum of C<sub>3</sub>N<sub>5</sub> 371 exhibits two <sup>13</sup>C NMR signals of approximately equal intensity <sub>372</sub> at 164 and 156 ppm for N<sub>2</sub>C-N=N- and CN<sub>3</sub> carbons 373 (Figure 5b).<sup>24,30,31</sup> The N<sub>2</sub>C-NHNH<sub>2</sub> carbon signal of MH <sub>374</sub> located at 160 ppm arising due to C-H functionalities 375 disappeared in the  ${}^{13}$ C NMR of C<sub>3</sub>N<sub>5</sub>, which confirms removal  ${}_{376}$ of -NHNH<sub>2</sub> protons and formation of an azide linkage during 377 polymerization step agreeing with <sup>15</sup>N CPMAS NMR, vide 378 infra. Furthermore, the appearance of equally intense (Cc:Ce/ 379 1:1.07) <sup>13</sup>C peaks in the <sup>13</sup>C NMR spectrum of C<sub>3</sub>N<sub>5</sub> suggests <sub>380</sub> that heptazine units are in the presence of a symmetric azo 381 bridging motif (where Cc corresponds to central carbons in 382 ring and Ce to external carbons bonded to azo N). A slight 383 shift to higher frequency in CN<sub>3</sub> carbon peaks from 154 ppm <sub>384</sub> in MH to 156 ppm in C<sub>3</sub>N<sub>5</sub> suggests shielding of carbons due 385 to N 2p overlap of azo and aromatic  $\pi$  system, which extends <sub>386</sub> the  $\pi$  conjugated network.<sup>32</sup> 387

The <sup>15</sup>N CPMAS NMR spectrum of MH exhibits four 388 389 signals, -207, -252, -273 and -317 ppm (Figure 5c).<sup>23a</sup> The 390 <sup>15</sup>N NMR signal at -207 ppm and another weak signal at  $_{391}$  –273 ppm were assigned to (NC<sub>2</sub>) and (NC<sub>3</sub>) nitrogens of the 392 heptazine motif,  $^{23a,31b,32,33}$  while the peaks at -252 and -317 393 ppm assigned to NH<sub>2</sub> and NH terminal nitrogens of hydrazino <sup>394</sup> moiety.<sup>33,34</sup> The transformation of MH to  $C_3N_5$  proceeds with 395 removal of NH<sub>3</sub> and formation of azo linkage which was 396 evident from the disappearance of  $NH_2$  and NH peaks at -252397 and -317 ppm in the <sup>15</sup>N NMR spectrum of  $C_3N_5$  (Figure 398 5d). The two NMR peaks in the <sup>15</sup>N NMR spectra of  $C_3N_5$  at  $_{399}$  –197 and –248 (weak) ppm were attributed to NC<sub>2</sub> and NC<sub>3</sub> 400 nitrogens of heptazine skeleton while another peak at -271401 ppm arose from -N=N- (and residual NHs) type nitrogens. 402 As the N atoms are in similar chemical environments, a 403 semiquantitative CPMAS NMR analysis of the <sup>15</sup>N peak areas 404 achieved by peak integration of NC2 and NC3 and -N=N-405 resonances was found give a ratio of 1.00:0.18:0.54, which was 406 in good agreement with the theoretical value (1.00:0.17:0.5)407 calculated for C<sub>3</sub>N<sub>5</sub> polymeric structure containing heptazine 408 units interconnected with azo linkage (Figure S1). Further-409 more, <sup>1</sup>H NMR of MH gave an intense peak at 5.11 ppm due 410 to NH and NH<sub>2</sub> hydrogens (Figure S4). This intense peak 411 disappeared in the <sup>1</sup>H NMR spectra of C<sub>3</sub>N<sub>5</sub> further 412 confirming the removal of NH hydrogens and a very broad 413 peak centered at 9.18 ppm appeared due to intercalated 414 hydrogen, and residual carboxy and aldehyde hydrogens 415 (essential for the CPMAS approach to function whereby <sup>1</sup>H 416 magnetization is transferred to <sup>13</sup>C and <sup>15</sup>N). All these NMR 417 results validate the successful synthesis of a modified carbon 418 nitride framework.

Fourier transform infrared (FTIR) spectroscopy was 419 420 employed to determine the change in functional moiety in 421 the material (Figure 6a-d). The FTIR spectrum of melem 422 shows characteristic broad peaks at 3109 cm<sup>-1</sup> due to the 423 combined symmetric and antisymmetric stretch vibrations of 424  $-\mathrm{NH}_2$  and  $-\mathrm{OH}$  ( $u_{\mathrm{N-H}}$  and  $u_{\mathrm{O-H}}$ ) groups. The IR bands at 425 1595, 1411, 1230 and 1078 cm<sup>-1</sup> are ascribed to the C-N 426 stretch ( $\nu_{C-N}$ ) of heptazine ( $C_6N_7$ ) aromatic nucleus (Figure 427 6a).<sup>18a,31b,34a,35</sup> The N–H stretch band ranging from 3153 to 428 2895 cm<sup>-1</sup> for MH was found to become broader due to 429 combinational symmetric and asymmetric N-H stretches of 430 -NH-NH<sub>2</sub> group in MH, which confirms the successful 431 transformation of -NH<sub>2</sub> moiety in melem to -NH-NH<sub>2</sub> in 432 melem hydrazine (Figure 6b). The broadening of the NH peak 433 was attributed to strong intermolecular hydrogen bonding in 434 MH molecules.<sup>35,36</sup> However, all stretching and bending peaks 435 due to heptazine aromatic ring skeleton remain preserved, 436 which indicates that the heptazine motif remains unchanged 437 during the hydrazine treatment. Additionally, some new peaks 438 emerged at 1095 and 965 cm<sup>-1</sup> implicating the N–N stretch 439 and -NH2 rocking vibration, respectively.<sup>18a,36,37</sup> Graphitic 440 carbon nitride shows characteristic peaks at 3145 cm<sup>-1</sup> due to <sup>441</sup> residual  $-NH_2$  and -OH stretch and 1639–1145 cm<sup>-1</sup> due to 442 triazine ring stretch and 798 cm<sup>-1</sup> for triazine ring bending 443 vibration was in good agreement with the reported literature 444 (Figure 6c).<sup>37,38</sup> After conversion of MH to  $C_3N_5$  by thermal 445 annealing, the intensity of  $-NH-NH_2$  peak of MH was 446 diminished which implicated the transformation of -NH-447 NH<sub>2</sub> group into azo (-N=N-) linkage through the removal 448 of NH<sub>3</sub> (Figure 6d). It is important to note that vibration of 449 symmetrical -N=N- azo linkage is forbidden due to which 450 no new sharp peak due to azo functionalities was observed.

The possibility of -NH-NH- bond can be neglected due to 451 the absence of any strong N—H band; however, very weak 452 broad peaks arise due to some residual  $-NH_2$  present at the 453 edge of the polymeric framework. This fact was well supported 454 by CHNS analysis, which showed the presence of only one H 455 for each stoichiometric  $C_3N_5$  unit (Table 1). Further, other 456 peaks of MH at 1095 and 965 cm<sup>-1</sup> due to N–N stretch and 457  $-NH_2$  rocking vibration disappear in  $C_3N_5$ , which confirmed 458 the transformation of hydrazine group into azo moiety. Peaks 459 corresponding to the  $C_3N_4$  framework at 1542, 1315 and 887 460 cm<sup>-1</sup> were absent in  $C_3N_5$ , which suggests an entirely different 461 network of  $C_3N_5$  in comparison to g- $C_3N_4$ .

The changes in phase structure and crystalline nature of 463 melem, MH, g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> were investigated through the 464 measurement of X-ray diffraction (XRD) (Figure 6). The XRD 465 pattern of melem demonstrated a series of peaks located at 466 12.5°, 13.6°, 16.7°, 18.4°, 19.7°, 22.0°, 25.2°, 27.2° and 30.4°, 467 in close agreement with previous reports (Figure 6e).<sup>38,39</sup> The 468 XRD results indicate the absence of any melamine impurity in 469 the melem sample.<sup>18b,39a</sup> Because of the transformation of 470 melem into melem hydrazine, the XRD pattern of MH 471 changed, with new peaks being observed at  $2\theta$  values of 7.3°, 472 7.9°, 8.4°, 12.9°, 13.7°, 14.8°, 25.1° and 28.0° (Figure 6f). Bulk 473 g-C<sub>3</sub>N<sub>4</sub> shows two distinct XRD peaks at  $2\theta$  values of 27.1° 474 and 13.0° indexed to the 002 and 100 planes of carbon nitride 475 materials (Figure 6g). The 002 peak with a 0.32 nm interplanar 476 d spacing was correlated to interplanar stacking of sheets while 477 100 peaks with a 0.68 nm spacing was specific to in-plane 478 structural packing of heptazine units (Figure 6g).<sup>18b,39b,40</sup> The 479 XRD pattern of C<sub>3</sub>N<sub>5</sub> exhibits one broad 002 peak at 27.6° 480 corresponded to 0.33 nm interplanar sheet distance. The slight 481 increase in  $2\theta$  value and d spacing can be explained due to 482 repulsion between electron-rich  $\pi$  conjugated C<sub>3</sub>N<sub>5</sub> sheets as in 483 graphite (0.34 nm) (Figure 6h). Further, the absence of 100 484 peak, a specific feature of in-plane packing, suggests distortion 485 in the carbon nitride framework and broadening of the 486 nanochannel distance between heptazine units due to azo 487 (-N=N-) bridging linkage, further consistent with <sup>13</sup>C and <sup>488</sup> <sup>15</sup>N NMR resonance broadening above, suggesting local/ 489 medium-range disorder. Also, bridging of two heptazine units 490 with two nitrogens through in-plane lattice packing is less 491 efficient in  $C_3N_5$  which was responsible for the absence of any 492 expected peak at lower  $2\theta$  values. These XRD results clearly 493 support the distinct structure of C<sub>3</sub>N<sub>5</sub> possessing azo linkage. 494

Raman spectra of melem acquired using 632 nm laser 495 excitation show characterstic fingerprint peaks of melem at 435 496 and 697 cm<sup>-1</sup> due to heptazine ring ( $C_6N_7$ ) breathing modes 497 and a broad hump at 1452 cm<sup>-1</sup> due to  $-NH_2$  bending mode 498 (Figure S5a).<sup>18a,40a</sup> Raman spectra of MH demonstrate many 499 signature peaks correlated to the core at 472, 744 and 1529 500 cm<sup>-1</sup>, which were shifted in comparison to melem due to 501 functionalization while other peaks due to various vibrations of 502 the heptazine nucleous and hydrazine group were observed at 503 127, 342, 537, 985, 1159, 1314 and 3071 cm<sup>-1</sup>, in good 504 agreement with the reported literature (Figure 505 S5b).<sup>18a,23a,40b,41</sup> The Raman spectra of  $g-C_3N_4$  display many so6 prominent peaks due to the heptazine framework at 471, 697 507 and 706 cm<sup>-1</sup> (heptazine ring breathing modes) and two 508 additional peaks at 1233 and 1567 cm<sup>-1</sup> corresponding to the 509 -NH<sub>2</sub> bending mode and graphitic G band (Figure S5c).<sup>23a,42</sup> 510 Further, the presence of a broad hump extended from 1100 to 511 1600 cm<sup>-1</sup> suggests multilayer stacking of g-C<sub>3</sub>N<sub>4</sub> sheets.<sup>41,43</sup> 512 In the Raman spectra of C<sub>3</sub>N<sub>5</sub>, only trace peaks of melem 513



300 400 500 600 700 800 400 450 500 550 600 Wavelength (nm) Wavelength (nm)

Figure 7. (a) DR-UV-vis spectra of  $g-C_3N_4$  (blue) and  $C_3N_5$  (red), with inset showing photographs of  $g-C_3N_4$  and  $C_3N_5$  samples and (b) Steady-state PL spectra of melem (black),  $g-C_3N_4$  (blue) and  $C_3N_5$  (red) obtained using an excitation wavelength of 360 nm.



**Figure 8.** (a) PL lifetime decay curves of  $g-C_3N_4$  (red; triexponential fit, yellow line) and  $C_3N_5$  (black, triexponential fit, cyan), (b) Schematics of various energy levels bands and possible route of charge carriers recombination (c) X-band EPR spectra of  $g-C_3N_4$  in the dark (blue), after light irradiation (orange dots) and  $C_3N_5$  in the dark (red) and after light irradiation (black dots) at room temperature, (d) Plausible molecular orbital overlap representation of  $C_3N_5$ .

<sup>514</sup> hydrazine motif are observed which indicates the complete <sup>515</sup> transformation of MH to  $C_3N_5$ . Two small peaks were <sup>516</sup> observed at 1085 and 1161 cm<sup>-1</sup> due to the mixed vibration of <sup>517</sup> heptazine motif and azo stretch (Figure S5d). A sharp peak at <sup>518</sup> 1609 cm<sup>-1</sup> originated due to the C=N stretching mode.

Figure 7a displays the diffuse reflectance UV—vis (DR-UV— 520 vis) spectra of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub>. The DR-UV—vis spectra of g-521 C<sub>3</sub>N<sub>4</sub> shows a characteristic absorption peak between 200 and 522 400 nm with a band tail extended up to 450 nm due to charge 523 transfer from the populated valence band of the nitrogen atom 524 (2p orbitals) to the conduction band of the carbon atom (2p 525 orbitals) of carbon nitride. The less intense absorption band at 330 nm is due to  $\pi \rightarrow \pi^*$  transition in the conjugated network 526 while another intense peak at ca. 387 nm appeared due to  $n \rightarrow 527$  $\pi^*$  transition from nitrogen nonbonding orbital to the aromatic 528 nonbonding orbital.<sup>12b,42-44</sup> The DR-UV-vis spectrum of 529  $C_3N_5$  demonstrates a drastic change in the UV-vis absorption 530 profile in comparison to g- $C_3N_4$  due to a more extended  $\pi$  531 conjugated network (Figure 7a).<sup>12b,45</sup> A broad absorption peak 532 around 393 nm in UV-vis spectrum of  $C_3N_5$  was attributed to 533  $n \rightarrow \pi^*$  transition from nitrogen nonbonding orbital to the  $\pi$  534 conjugated nonbonding orbital. The absorption spectrum of 535  $C_3N_5$  was red-shifted showing band tailing up to 670 nm, due 536 to an extended  $\pi$  conjugated network arising from the overlap 537

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538 between N 2p orbitals of bridging azo moieties and N 2p in 539 heptazine  $\pi$  conjugated system. Further residual -NH<sub>2</sub> also s40 contributes to the delocalized aromatic  $\pi$  conjugated system. 541 Because of this, the position of the valence band gets upshifted 542 and  $\pi \rightarrow \pi^*$  transition occurs at relatively low energy which 543 facilitates the absorption of a large fraction of the visible 544 spectrum and results in the sample displaying an orange color. 545 Further, the optical bandgaps of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> were 546 determined using a Tauc plot by plotting a graph between 547  $(\alpha h\nu)^{1/2}$  vs  $h\nu$  and extrapolation of the linear tangent to 548 abscissa; where  $\alpha$  is absorption coefficient, h is plank constant 549 and  $\nu$  is light frequency (Figure S6a). From the Tauc plot, the 550 value of bandgap for g-C<sub>3</sub>N<sub>4</sub> was estimated to be 2.65 eV 551 corresponding to a band-edge at a wavelength of 467 nm, in 552 good agreement with the bandgap values reported in the 553 literature.<sup>46</sup> The bandgap value of  $C_3N_5$  was calculated to be 554 1.76 eV corresponding to a band-edge at a wavelength of 707 555 nm.

Photoluminescence (PL) spectra were collected by exciting 556 557 samples using 360 nm photons to probe radiative recombina-558 tion (Figure 7b). The PL spectrum of melem consists of an 559 intense emission peak centered at 441 nm, which is indicative 560 of radiative recombination of carriers within the melem 561 unit.<sup>39a,44</sup> It is important to note here that melem exhibits 562 excitation wavelength-dependent PL emission. On the other 563 hand, g-C<sub>3</sub>N<sub>4</sub> showed a sharp emission peak at 468 nm, which 564 did not shift upon changing the excitation wavelength. This 565 peak is attributed to fast interlayer carrier recombination in 566 multilayered sheets of bulk g-C<sub>3</sub>N<sub>4</sub>.<sup>45,47</sup> Surprisingly, C<sub>3</sub>N<sub>5</sub> 567 does not exhibit any distinguishing PL peak, which might be 568 indicative of efficient charge separation between the bulk and 569 the surface. Such charge transfer excitonic states involving the 570 bulk and the surface have also been observed in other 571 conjugated organic semiconductors that possess an extended 572  $\pi$ -conjugated network that prevents radiative recombination by 573 delocalizing the Frenkel exciton. However, because of 574 conductive conjugated surface, nonradiative charge recombi-575 nation can take place over new localized states in the sheets 576 scaffold.<sup>4</sup>

In order to investigate the lifetime of excited charged species, and charge separation processes, we collected timeresolved photoluminesece (TRPL) spectra of  $g-C_3N_4$  and  $C_3N_5$  using a single photon picosecond pulsed laser at a wavelength of 405 nm. Figure 8 displays the PL lifetime decay sez curves of  $g-C_3N_4$  and  $C_3N_5$ . The PL decay curve was fitted triexponentially using the following equation:

$${}_{4} I(t) = A_1 e^{-t/\tau 1} + A_2 e^{-t/\tau 2} + A_3 e^{-t/\tau 3}$$
(1)

58

t2

s85 where,  $A_1$ ,  $A_2$  and  $A_3$  represent the normalized amplitudes of 586 each decay component and  $au_1$ ,  $au_2$  and  $au_3$  are values of the 587 lifetime components, respectively. The existence of three 588 radiative lifetimes in the fitted PL lifetime spectra of g-C<sub>3</sub>N<sub>4</sub> 589 and C<sub>3</sub>N<sub>5</sub> was in good agreement with previously reported 590 carbon nitride based materials.<sup>49</sup> The obtained values of 591 lifetimes and their fractional components are given in Table 2. The three components in the PL lifetime decay curve of g-592 593  $C_3N_4$  can be assigned to various energy states in g- $C_3N_4$ 594 formed by the overlap of C and N sp<sup>2</sup> and sp<sup>3</sup> hybridized 595 orbitals and the presence of lone pairs of electrons, which allow 596 for various radiative transitions. g-C<sub>3</sub>N<sub>4</sub> is composed of tri-s-597 triazine  $(C_6N_7)$  units interconnected with tertiary nitrogen 598 atoms where C-N sp<sup>3</sup> hybridized state constitute high energy 599  $\sigma$  and  $\sigma^*$  molecular orbitals while C–N sp<sup>2</sup> hybridization gives

Table 2. PL Lifetime of Phogenerated Charge Carrier and Their Relative Contribution in  $g-C_3N_4$  and  $C_3N_5$ 

sample	$egin{array}{c}  au_1 \ (\mathrm{ns}) \ [A_1] \end{array}$	$ au_1(\mathrm{ns}) \; [A_1]$	$ au_1(ns) \ [A_1]$	average lifetime $( au_{ ext{avg}},  ext{ ns})$
$g-C_3N_4$	3.31 [0.34]	0.75 [0.63]	25.02 [0.05]	12.43
$C_3N_5$	8.10 [0.07]	2.11 [0.26]	0.28 [0.73]	4.40

rise to a conjugated network resulting in low energy  $\pi$  bonding 600 and  $\pi^*$  antibonding orbital, which constitutes the valence and 601 conduction bands, respectively.<sup>50</sup> The presence of unbonded 602 lone pairs of electrons on pyridinic N atoms creates energy 603 levels just below the  $\pi$  bonding orbital and their overlap with 604 the  $\pi$  conjugated system can further decrease the energy of the 605  $\pi$  molecular orbital resulting in the reduction of the bandgap.<sup>51</sup> 606 The first two shorter lifetime components of 3.31 and 0.75 ns 607 with 34% and 63% contribution in g-C<sub>3</sub>N<sub>4</sub> correspond to 608 charge carrier recombination from  $\sigma^*$  and  $\pi^*$  antibonding to  $\pi$  609 MO.<sup>52</sup> The third longer lifetime component of 25.02 ns with a 610 relative low contribution originated due to intersystem crossing 611 (ISC) of electron from  $\sigma^*$  and  $\pi^*$  orbital followed by radiative 612 relaxation to conjugated  $\pi$  orbital and trap-assisted radiative 613 recombination.<sup>53</sup> The first two lifetimes of C<sub>3</sub>N<sub>5</sub> at 8.10 and 614 2.11 ns with 7% and 26% contributions in the PL decay curve 615 were significantly longer lived in comparison to g-C<sub>3</sub>N<sub>4</sub>, 616 strongly suggesting that the introduction of azo moiety extends 617  $\pi$  conjugated network which facilitates better charge carrier 618 mobility on C<sub>3</sub>N<sub>5</sub> sheets (delocalized the exciton, as 619 mentioned previously) and prevents faster charge carrier 620 recombination.<sup>54</sup> Further, because of extended conjugation, 621 the difference between  $\sigma^*$  and  $\pi^*$  band gets decreased, which 622 is also evident in Mott-Schottky measurement (Figure 623 S6b).<sup>51a</sup> The low energy difference between  $\sigma^*$  and  $\pi^*$  624 accelerates the transfer of electrons from  $\sigma^*$  and  $\pi^*$  orbital via 625 intersystem crossing followed by radiative relaxation, which 626 was evident from higher percentage contribution of the third 627 lifetime component (73%). 62.8

The average lifetime  $(\tau_{avg})$ , which is regarded as coherent 629 measure to evaluate the rate of spontaneous emission, was 630 calculated from the three lifetime components using the 631 following expression: 632

$$\tau_{\text{avg}} = (A_1 \tau_1^2 + A_2 \tau_2^2 + A_3 \tau_3^2) / (A_1 \tau_1 + A_2 \tau_2 + A_3 \tau_3)$$
(2) 633

From eq 2, the average lifetimes of  $g-C_3N_4$  and  $C_3N_5$  were 634 calculated to be 12.43 and 4.40 ns, respectively. The decreased 635 lifetime of the  $C_3N_5$  in comparison to  $g-C_3N_4$  coupled with the 636 very weak photoluminescence of  $C_3N_5$  (as shown in Figure 7b) 637 is indicative of fast quenching of the C<sub>3</sub>N<sub>5</sub> luminescence. The 638 fast quenching might originate from improved charge 639 separation in  $C_3N_5$  due to a larger conjugated  $\pi$  network but 640 might also be due to stronger nonradiative transitions. Fast 641 exciton dissociation with concomitant high carrier mobility can 642 result in photogenerated electrons finding trap sites (and 643 moving to them) and recombining by nonradiative proc- 644 esses.<sup>48a</sup> The aforementioned processes are highly likely in 645  $C_3N_5$  since the presence of azo bonds extends the  $\pi$  network 646 because of overlap of N 2p orbital on azo nitrogens with the  $\pi$  647 network of heptazine motif due to which electrons can move 648 within  $C_3N_5$  scaffold freely. The lower PL lifetime of  $C_3N_5$  in 649 comparison to g-C<sub>3</sub>N<sub>4</sub> was consistent with steady-state PL 650 where C<sub>3</sub>N<sub>5</sub> shows prodigious quenching in its PL spectrum. 651



Figure 9. (a) UV-vis absorption spectra of MB (blue),  $C_3N_5$  (red) and  $C_3N_5/MB$  solution just after 1 min of absorption (green). Inset shows photographs of (1) MB before absorption, (2) after absorption and (3) solution after centrifugation. (b) Possible ionic and  $\pi-\pi$  stacking interaction between methylene blue and  $C_3N_5$ .

Electron paramagnetic resonance (EPR) spectra of  $g-C_3N_4$ 652 653 and C<sub>3</sub>N<sub>5</sub> to elucidate electronic nature and band excited 654 paramagnetic species were collected under dark and UV 655 irradiation at room temperature (Figure 8b). The EPR spectra 656 of g-C<sub>3</sub>N<sub>4</sub> under dark conditions exhibits an intense Lorentzian 657 EPR resonance signal located at a g-factor of 2.003. The 658 observed EPR signal originated due to the presence of 659 unpaired electrons in the sp<sub>2</sub> hybridized aromatic  $\pi$ -system 660 which was in good agreement with previous reports.<sup>36,55</sup> The 661 EPR signal intensity of g-C<sub>3</sub>N<sub>4</sub> increased after UV irradiation, 662 attributed to populated unpaired electrons in the conduction 663 band due to  $\pi - \pi^*$  and N nonbonding to  $\pi^*$   $(n - \pi^*)$  transition 664 followed by slow relaxation via ISC. The observed EPR signal  $_{665}$  of C<sub>3</sub>N<sub>5</sub> was also observed at 2.003 g-value, which implies basic 666 graphitic heptazine skeleton remains intact in C<sub>3</sub>N<sub>5</sub> frame-<sup>667</sup> work.<sup>56</sup> Further, after irradiation with UV light, the EPR signal 668 intensity of C<sub>3</sub>N<sub>5</sub> was also enhanced due to increased numbers 669 of unpaired electrons in the conduction band. However, the 670 overall EPR signal intensity of C3N5 in both the dark and 671 under UV illumination was significantly weaker in comparison  $_{672}$  to g-C<sub>3</sub>N<sub>4</sub>, which was attributed to a lesser number of unpaired 673 electrons in C<sub>3</sub>N<sub>5</sub>, which in turn can be taken as evidence of 674 the presence of extra N atoms outside the heptazine nucleus in 675 comparison to conventional N-rich carbon nitride materials 676 where N atoms substitute C atoms in the heptazine motif. It is 677 well documented in the literature that substitution of sp<sup>2</sup> 678 hybridized +4 state C atom in heptazine motif with sp<sup>2</sup> 679 hybridized +3 state N atom will liberate extra electrons in 680 the aromatic system, which will distort electronic symme-681 try<sup>16,47,57</sup> and also increase EPR signal intensity. However, in 682 the case of C<sub>3</sub>N<sub>5</sub>, the additional N atom makes an azo bond with an N atom outside the ring via  $\pi$  overlap and the extra 683 electrons remain in the form of lone pairs (Figure 8d). 684

Fluorescence lifetime imaging microscopy (FLIM) of samples at different spots was used to probe the homogeneity of samples and to determine the nature of the fluorescence (Figure S7). The PL spectra of  $g-C_3N_4$  samples obtained from different spots exhibited identical emission profiles with a sharp intense peak at 480 nm, which was in good agreement with the steady-state PL spectrum (Figure 7b). The slight red spit in the emission peak (Figure S7a) is attributed to the

difference in the mechanism of excitation (750 nm two-photon 693 excitation source for FLIM, 360 nm single photon excitation in 694 Figure 7b). Furthermore, the emission spectrum of  $C_3N_5$  695 displays two relatively weak peaks centered around 410 and 696 490 nm which likely originated from some relatively smaller 697 C<sub>3</sub>N<sub>5</sub> polymeric fragments and heptazine networks (Figure 698 S7c). The smaller fragments are consistent with a lesser 699 number of MH units and therefore exhibit PL properties closer 700 to melem. FLIM images of g-C<sub>3</sub>N<sub>4</sub> were brighter than C<sub>3</sub>N<sub>5</sub> 701 which further supports our inference that the charge separation 702 process was dominant in  $C_3N_5$  samples (Figure S7b,d). The 703 C<sub>3</sub>N<sub>5</sub>/MB samples obtained after methylene blue (MB) dye 704 adsorption displayed relatively strong PL and brighter FLIM 705 images due to the presence of MB in the composite (Figure 706 S7e,f). The absence of PL quenching in the  $C_3N_5/MB_{707}$ composite further suggests the absence of photoinduced 708 charge transfer between the methylene blue and  $C_3N_5$ . 709

The synthesized  $C_3N_5$  material was explored for dye 710 adsorption studies using methylene blue (MB) as a model 711 dye. Methylene blue is a staining dye widely used in the paper, 712 textile and leather industries which also constitutes a good 713 example of a colored water contaminant, which due to its 714 excellent visible light absorption, reduces light penetration in 715 aqueous ambients and adversely affects aquatic flora and fauna. 716 All dye adsorption studies were carried out at room 717 temperature and under dark conditions. UV-vis spectra of 718 samples were collected for determining the concentration of 719 MB solutions during dye adsorption experiments (for 720 experimental details, see Supporting Information). MB has a 721 sharp peak at 664 nm due to  $\pi - \pi^*$  transition and a shoulder 722 around 614 nm which represents MB present in dimeric and 723 polymeric  $\pi$  stacked forms in water (Figure 9a). After the 724 f9 addition of  $C_3N_5$  sample into methylene blue solution, the 725 color of the solution instantaneously turned green. The green 726 solution after centrifugation turned completely colorless, which 727 demonstrated the prompt adsorption of MB dye over the 728 surface of C<sub>3</sub>N<sub>5</sub> and subsequent settling of the MB adsorbed 729  $C_3N_5$  during centrifugation. The obtained solid after 730 centrifugation (denoted as C<sub>3</sub>N<sub>5</sub>/MB) exhibits a sharp 731 absorption peak intermediate between C<sub>3</sub>N<sub>5</sub> and MB with a 732 broad peak centered at 680 nm. The redshifting in the peak of 733



**Figure 10.** Kinetics of MB dye adsorption on  $g-C_3N_4$  and MB displaying (a) pseudo-first-order fitted curve, (b) pseudo-second-order fitted curve and MB adsorption isotherms fitted by Langmuir and Freundlich model of (c)  $g-C_3N_4$  and (d)  $C_3N_5$ , respectively.  $q_e$  is the amount of dyes adsorbed at equilibrium while  $C_e$  is the equilibrium concentration of MB.

734 C<sub>3</sub>N<sub>5</sub> from 664 to 680 nm is attributed to the transformation 735 of MB into monomeric form and some degree of ground state 736 charge transfer from C<sub>3</sub>N<sub>5</sub> to MB during adsorption on the surface of C<sub>3</sub>N<sub>5</sub>. The dye adsorption performance of C<sub>3</sub>N<sub>5</sub> was 737 much higher than g-C<sub>3</sub>N<sub>4</sub>. MB is a well-known cationic dye 738 possessing positive charge centered on the S atom in aqueous 739 solutions.<sup>58</sup> On the other hand, the surface of  $C_3N_5$  material 740 has electron-rich character due to the presence of secondary N 741 (NC<sub>2</sub>) in heptazine moieties, terminal  $-NH_2$  and  $\pi$  extended 742 network. Therefore, electrostatic interactions between the 743 positively charged MB molecule and negatively charged C<sub>3</sub>N<sub>5</sub> 744 745 are likely responsible for the instantaneous adsorption.<sup>54,59</sup> To 746 confirm negative charge on the surface of  $C_3N_5$ ,  $\zeta$ -potential 747 measurement was performed which depicts average surface charge of -36.2 mV and proves the electron-rich surface of 748  $C_3N_5$  (Figure S8). Further, MB can also adsorb on the surface 749 of  $C_3N_5$  via  $\pi-\pi$  stacking between aromatic conjugated 750 751 network of MB and  $\pi$  framework of C<sub>3</sub>N<sub>5</sub> (Figure 9b).<sup>60</sup> To investigate the role of surface specific properties in the 752 enhanced adsorption profile, Brunauer-Emmett-Teller 753 (BET) surface area ( $S_{BET}$ ), pore volume ( $V_p$ ) and pore 754 755 diameter  $(r_p)$  of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> were measured by N<sub>2</sub> 756 adsorption and desorption. The obtained BET surface area, 757 pore volume and pore diameter for g-C<sub>3</sub>N<sub>4</sub> were found to be  $_{758}$  11.47 m  $^2$  g  $^{-1}$  , 0.095 cm  $^3$  and 19.13 nm while these values for 759  $C_3N_5$  were found to be 1.78 m<sup>2</sup> g<sup>-1</sup>, 0.002 cm<sup>3</sup> g<sup>-1</sup> and 16.98 760 nm, respectively. The obtained surface values indicate a 761 decrement in the surface area of C<sub>3</sub>N<sub>5</sub> in comparison to g-762 C<sub>3</sub>N<sub>4</sub>. The relatively low surface area of C<sub>3</sub>N<sub>5</sub> might be due to 763 the less gas evolution (three NH<sub>3</sub> per heptazine unit) from 764 melem hydrazine precursor during thermal annealing step

while the formation of  $g-C_3N_4$  from melamine precursor 765 releases six  $NH_3$  molecule per heptazine unit. Further, 766 hydrogen bonded melem hydrazine precursor might promote 767 in-plane cross-linking of heptazine units leading to a stacked 768 sheets type structure which reduces the effective accessible 769 surface area. Contrarily, in  $g-C_3N_4$  ring formation and 770 polymerization step can produce cross-linking between sheets 771 giving a porous structure with high surface area. The obtained 772 results suggest that an electronic interaction between  $C_3N_5$  and 773 MB is responsible for the superior adsorption performance of 774  $C_3N_5$  rather than an increased surface area.

To investigate whether the nature of adsorption was 776 chemisorption or physisorption, and to explore the possibility 777 of any chemical bonding, the C<sub>3</sub>N<sub>5</sub>/MB composite was 778 analyzed using NMR spectroscopy. The <sup>13</sup>C NMR spectrum 779 of C<sub>3</sub>N<sub>5</sub>/MB composite did not show any change in peak 780 position and intensity of C3N5, which demonstrated the 781 adsorption of MB on  $C_3N_5$  to be purely physisorptive in nature 782 (Figure S9d). FTIR, Raman and PL spectra of C<sub>3</sub>N<sub>5</sub>/MB 783 composite displayed various cumulative peaks and signals due 784 to the presence of MB in the C<sub>3</sub>N<sub>5</sub>/MB composite. However, 785 no evident signals for any chemical interaction can be 786 identified, which further supports a purely physical interaction 787 (physisorption) between  $C_3N_5$  and MB (Figure S9a-c). 788 Additionally, XPS spectra of C<sub>3</sub>N<sub>5</sub>/MB composite were 789 identical to pristine C3N5 samples which revealed that C3N5 790 signals dominated over MB, and no change in BE value was 791 observed which ruled out the possibility of any chemical bond 792 formation between  $C_3N_5$  and MB (Figure S10). 793

To quantify the excellent dye adsorption capacity of  $C_3N_5$ , 794 various parameters such as the adsorption capacity, adsorption 795

		pseudo-first-order			pseudo-second-order			
serial no.	sample name	$k  (s^{-1})$	$q_{\rm e}~({\rm mg~g^{-1}})$	$R^2$	$k (s^{-1} mg^{-1} L)$	$q_{\rm e}({\rm mg~g^{-1}})$	$R^2$	
1	$g-C_3N_4$	0.16	2.35	0.96	0.08	2.6	0.99	
2	C <sub>3</sub> N <sub>5</sub>	6.35	6.83	0.98	2.24	6.95	0.99	
		Langmuir			Freundlich			
serial no.	sample name	$Q (mg g^{-1})$	$b (L mg^{-1})$	$R^2$	$K (\mathrm{mg}^{1-n} \mathrm{L}^{n} \mathrm{g}^{-1})$	n	$R^2$	
1.	g-C <sub>3</sub> N <sub>4</sub>	6.03	0.13	0.97	1.21	0.43	0.96	
2.	C <sub>3</sub> N <sub>5</sub>	42.32	0.05	0.98	2.40	0.78	0.97	



**Figure 11.** (a) XPS valence band spectra of  $C_3N_5$  for determining energy levels. (b) Density of state revealing band structure of  $g-C_3N_4$  and  $C_3N_5$ . (c) Linear sweep voltammogram showing current–potential characteristics of  $g-C_3N_4$  (blue) and  $C_3N_5$  (red) measured in 0.1 M Na<sub>2</sub>SO<sub>4</sub> solution AM1.5G light irradiation (100 mW cm<sup>-2</sup>) and under dark conditions. (d) Light on–off showing photocurrent response vs applied voltage by using 450 nm wavelength light (54.15 mW cm<sup>-2</sup>) for  $g-C_3N_4$  (blue) and  $C_3N_5$  (red).

<sup>796</sup> constants, linear regression correlation coefficient, and <sup>797</sup> adsorption isotherm were measured and compared with <sup>798</sup> pristine g-C<sub>3</sub>N<sub>4</sub> (Figure 10 and Table 3). The adsorption <sup>799</sup> capacity (amount of dye adsorbed) of g-C<sub>3</sub>N<sub>4</sub> and MHP <sup>800</sup> materials was calculated using eq 3:

$$q = \frac{(C - C_{\rm e})V}{m} \tag{3}$$

<sup>802</sup> Where *q* is the adsorption capacity, *V* is the volume of MB <sup>803</sup> solution, *m* is the mass of the added adsorbent, and *C* and  $C_e$ <sup>804</sup> are the initial and equilibrium concentrations of MB, <sup>805</sup> respectively. The kinetics of methylene blue adsorption on <sup>806</sup> the surface of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> were investigated using first-<sup>807</sup> and second-order adsorption kinetics using eqs 4 and 5:

$$q_t = q_e (1 - e^{-kt}) \tag{4}$$

$$q_{t} = \frac{kq_{e}^{2}t}{1 + kq_{e}t}$$
(5) 809

Where  $q_e$  is adsorbed amount of dye after reaching equilibrium 810 and  $q_t$  is the adsorbed amount at time t, and k is the pseudo- 811 first-order or pseudo-second-order adsorption rate constant. 812

The results obtained using pseudo-first-order and pseudo- \$13 second-order kinetics are displayed in Table 3 and Figure \$14 10a,b. The kinetic studies clearly demonstrate that the \$15 prepared  $C_3N_5$  samples can reach approximately 95% \$16 adsorption–desorption equilibrium instantaneously (1 min), \$17 and complete adsorption–desorption equilibrium within 10 \$18 min, which is an extraordinary performance compared to \$19 previously reported carbon nitride and carbon based materials \$20 which usually take 45 min to achieve equilibrium.<sup>61</sup> In \$21 addition, the kinetics study indicated that the adsorption of \$22 methylene blue on the  $C_3N_5$  and  $g-C_3N_4$  materials follows \$23 pseudo-second-order adsorption kinetics, which agreed well \$24

801

825 with previous reports.<sup>61a</sup> For isotherm studies, standard s26 solutions of 5, 10, 15, 20, 25 and 30 ppm MB in water were 827 prepared; 50 mL of these standard solutions was placed in a 828 beaker and 50 mg of the adsorbents was added to them. The 829 solutions were kept under strong stirring for 30 min under dark 830 conditions to reach equilibrium, and then the concentration of 831 methylene blue was calculated using UV-vis spectroscopy (see 832 Supporting Information for details). The adsorption isotherms 833 of methylene blue were investigated in terms of the 834 Langmuir<sup>61b,62</sup> and Freundlich models<sup>61b,63</sup> (eqs 6 and 7, 835 respectively), and the results for  $g-C_3N_4$  and  $C_3N_5$  are 836 displayed in Figure 10c,d, respectively; the relevant constants 837 are reported in Table 3. It can be seen from Figure 10 and 838 Table 3 that the value of  $R^2$  extracted by employing the 839 Langmuir isotherm model was higher than the  $R^2$  value 840 obtained from the Freundlich isotherm model, indicating that 841 the Langmuir model representing complete monolayer cover-842 age on homogeneous sites was successful in predicting the <sup>843</sup> adsorption of methylene blue on both  $g-C_3N_4$  and  $C_3N_5$ .

$$q_{\rm e} = \frac{QbC_{\rm e}}{(1+bC_{\rm e})} \tag{6}$$

$$q_{e} = KC_{e}^{n}$$
<sup>(7)</sup>

844

f11

846 Where  $q_e$  is adsorbed amount of dye after reaching equilibrium 847 (mg g<sup>-1</sup>), R is correlation coefficient, Q is the monolayer 848 adsorption capacity (mg g<sup>-1</sup>), b is the adsorption coefficient (L 849 mg<sup>-1</sup>),  $C_e$  is the equilibrium concentration and K is the 850 Freundlich constant.

To check whether  $C_3N_5$  material displays any visible light 851 852 induced dye degradation activity, 50 mL of 50 ppm MB 853 containing solution was charged with 50 mg of C<sub>3</sub>N<sub>5</sub> catalyst 854 and stirred in the dark for 30 min to reach adsorption-855 desorption equilibrium. Subsequently, the obtained suspension 856 was irradiated under simulated sunlight (AM1.5G, 100 mW 857 cm<sup>-2</sup>). After every 10 min, 1 mL of sample was withdrawn and 858 centrifuged to remove solid C<sub>3</sub>N<sub>5</sub> and the supernatant liquid 859 was analyzed with UV-vis spectroscopy. The UV-vis analysis 860 indicated that the concentration of MB solution does not 861 change even after 8 h of irradiation. These results suggest that  $_{862}$  C<sub>3</sub>N<sub>5</sub> is not active for dye degradation, which might be because 863 of unfavorable band alignment. To understand the band 864 structure of C<sub>3</sub>N<sub>5</sub>, Mott-Schottky plots were obtained in 0.5 865 M Na<sub>2</sub>SO<sub>4</sub> solution (Figure S6b). From the Mott–Schottky 866 plot, the flat band positions of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> were found to 867 be -1.05 and -0.91 V vs Ag/AgCl, respectively, which can be 868 considered the conduction band position if the Fermi level lies 869 just below conduction band (strong *n*-type character). Using 870 the bandgap values obtained from the Tauc plot (2.65 eV for 871 g-C<sub>3</sub>N<sub>4</sub> and 1.76 eV for C<sub>3</sub>N<sub>5</sub>), the positions of the valence 872 band edge for g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> were calculated to be +1.60 873 and +0.85 V vs Ag/AgCl, respectively. Since the standard band 874 edge positions are usually expressed with reference to NHE,  $_{875}$  the CB and VB positions of  $g-C_3N_4$  were calculated to -0.85876 and +1.80 V vs NHE at pH 0, while CB and VB positions of  $_{877}$  C<sub>3</sub>N<sub>5</sub> were found to be -0.72 and +1.04 V vs NHE at pH 0. XPS valence band spectra of C<sub>3</sub>N<sub>5</sub> was collected to get 878 879 further information regarding the band structure (Figure 11a). 880 The intersecting point obtained by extrapolation of XPS VB 881 spectra on x and y axes gave the value of valence band  $_{882}$  maximum (VB<sub>max</sub>). The VB<sub>max</sub> of C<sub>3</sub>N<sub>5</sub> was calculated to be 883 +0.95 eV, which was approximately the same (+1.05 V)

obtained from the Mott–Schottky measurements and UV–vis <sup>884</sup> data. Further, by using XPS VB and optical bandgap (1.76 eV) <sup>885</sup> values, the  $CB_{min}$  and  $VB_{max}$  of  $C_3N_5$  were calculated to be <sup>886</sup> –0.79 and +0.97 eV, while for g- $C_3N_4$ ,  $CB_{min}$  and  $VB_{max}$  <sup>887</sup> positions were found to be –0.85 and +1.80 eV, respectively. <sup>888</sup> Figure 11b shows a schematic illustration of the density of <sup>889</sup> states (DOS) distribution in  $C_3N_5$  and g- $C_3N_4$ . <sup>890</sup>

The dye degradation process begins with the reaction with • 891 OH radical originating from photogenerated holes in the 892 valence band of the semiconductor. The oxidation potential of 893 water to generate •OH radical (H<sub>2</sub>O/•OH) is +2.38 V vs NHE 894 at pH 0, which requires highly oxidative holes. Another route 895 for the generation of  $\cdot$ OH radicals is the reduction of O<sub>2</sub> to 896  $O_2^{\bullet-}$  anion radical ( $O_2/O_2^{\bullet-}$ , -0.33 V vs NHE at pH 0) at the 897 conduction band followed by reaction with protons to afford • 898 OH radicals.<sup>63,65</sup> However, for this process required protons 899 should be derived from water oxidation  $(H_2O/O_2, +1.23 \text{ V vs }_{900} \text{ NHE at pH } 0)$ .<sup>64,66</sup> Unfortunately, the valence band position 901 of C<sub>3</sub>N<sub>5</sub> is just +1.04 V vs NHE, which cannot facilitate water 902 oxidation thus explaining the absence of photocatalytic activity 903 for MB degradation. Nyquist plots of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> 904 determined with electrochemical impedance spectroscopy 905 (EIS) under dark and AM1.5G irradiation demonstrate that 906 the semicircle for C<sub>3</sub>N<sub>5</sub> was larger than for g-C<sub>3</sub>N<sub>4</sub>, which 907 represents a higher charge transfer resistance in C<sub>3</sub>N<sub>5</sub> 908 compared to g-C<sub>3</sub>N<sub>4</sub>; a higher charge carrier recombination 909 is indicated in  $C_3N_5$  (Figure S11). 910

Because of the unfavorable band edge positions of C<sub>3</sub>N<sub>5</sub> 911 (CB = -0.71 V and VB = +1.04 V vs NHE at pH 0), it is not 912 able to function as a stand-alone catalyst for the photo- 913 electrochemical splitting of water. However, the excellent 914 visible light absorption of C3N5 encouraged us to investigate 915 the photosensitizing effect of C<sub>3</sub>N<sub>5</sub> to increase the photo- 916 catalytic performance of TiO<sub>2</sub> (a wide bandgap semi- 917 conductor).<sup>67</sup> The conduction band of  $C_3N_5$  (-0.72 V vs 918 NHE) was more negative than the conduction band of  $TiO_2$  919 (-0.1 V vs NHE), which favors transfer of photogenerated 920 electrons in the CB of  $C_3N_5$  to the CB of  $TiO_2^{-68}$  To measure 921 photosensitizing performance, C<sub>3</sub>N<sub>5</sub> and g-C<sub>3</sub>N<sub>4</sub> powders were 922 mixed with TiO<sub>2</sub> nanoparticles in  $\alpha$ -terpineol solution (film- 923) forming agent) followed by drop-casting on FTO:glass 924 substrates coated with a thin ( $\sim$  50 nm) blocking layer of 925 TiO<sub>2</sub>. A three electrode setup consisting of the samples as the 926 photoanode (working electrode), Pt as cathode (counter 927 electrode) and Ag/AgCl reference electrode was used for 928 photoelectrochemical water splitting experiments in 0.1 M 929 Na<sub>2</sub>SO<sub>4</sub> electrolyte, while a Class A solar simulator was used as 930 the source of AM1.5G simulated sunlight (100 mW cm<sup>-2</sup>). 931 Linear sweep voltammograms of electrodes consisting of C<sub>3</sub>N<sub>5</sub> 932 and pristine g-C<sub>3</sub>N<sub>4</sub> samples mixed with TiO<sub>2</sub> NPs are shown 933 in Figure 11a. It can be seen from Figure 11a that the 934 photocurrent density for C3N5 sensitized TiO2 was much 935 higher than g-C<sub>3</sub>N<sub>4</sub> sensitized TiO<sub>2</sub>. The current density for 936 C<sub>3</sub>N<sub>5</sub> and g-C<sub>3</sub>N<sub>4</sub> sample blended TiO<sub>2</sub> sample was found to 937 be 152 and 100  $\mu$ A cm<sup>-2</sup> at an applied potential of +0.6 V vs 938 NHE (or 1.23 V vs NHE). To probe the improved 939 photosensitizing performance in the visible region, on-off 940 experiments using a 450 nm LED (54.15 mW cm<sup>-2</sup>) were 941 carried out, which clearly show the alternate drop and rise in 942 photocurrents in on-off cycles (Figure 11b). Figure 11b also 943 shows that the magnitude of the photocurrent was higher for 944 the C<sub>3</sub>N<sub>5</sub> sample. A similar pattern in the on-off cycle was 945 observed when samples were irradiated with 505 nm LED 946



**Figure 12.** (a) Current–voltage characteristics of perovskite solar cells made with bare  $PbX_{22}$  4 wt % of g- $C_3N_4$  and  $C_3N_5$  under AM1.5 G one sun illumination. (b) Mott–Schottky plot of the perovskite solar cells based undoped and g- $C_3N_4/C_3N_5$ -doped perovskite active layers. (c) Recombination resistance of perovskite solar cell based on undoped and doped Perovskite layer with CN and MHP in dark conditions. The corresponding equivalent circuit is shown in insets where  $R_s$  is series resistance, *C* is high-frequency capacitance, *R* is recombination resistance and *Q* is a constant phase element (CPE) with coefficient *N*. (d–i) Nyquist plots for perovskite solar cells made with bare  $PbX_{22}$  g- $C_3N_4$  and  $C_3N_5$  doping under dark conditions at 0.0, 0.2, 0.4, 0.6, 0.8 and 1.0 V.

947 (40.48 mW cm<sup>-2</sup>), confirming the improved photosensitizing 948 properties of  $C_3N_5$  at longer wavelengths (Figure S12). Further, photoelectrochemical water splitting experiment 949 carried out using Na<sub>2</sub>S (2.0 mmol) as hole scavenger showed 950 enhanced photocurrent density, reaching up to 465  $\mu$ A cm<sup>-2</sup> 951 for C<sub>3</sub>N<sub>5</sub> under AM 1.5 G irradiation (>420 nm) (Figure S13). 952 Under identical conditions, the value of photocurrent density 953 for g-C<sub>3</sub>N<sub>4</sub> was found to be 373  $\mu$ A cm<sup>-2</sup> (Figure S13a). A 954 similar pattern was followed at higher wavelengths and 955 calculated current density for C3N5 was found to be 454 and 956  $_{957}$  145  $\mu$ A cm<sup>-2</sup> at 450 and 505 nm, while for g-C<sub>3</sub>N<sub>4</sub> the value of current density was found to be 275 and 80  $\mu$ A cm<sup>-2</sup>, 958 respectively (Figure S13b). Photocurrent response of  $C_3N_5$  as 959 960 a function of time during light on-off cycle does not change significantly compared to g-C<sub>3</sub>N<sub>4</sub>, which demonstrates 961 962 resiliency of C3N5 under reaction conditions and charge flow (Figure S14). The maximum applied bias photon-to-current 963 964 efficiency (ABPE) and incident photon-to-current efficiency 965 (IPCE) achieved by  $C_3N_5$  was 0.059 and 2.33% (at 450 nm),

while the value for  $g-C_3N_4$  was 0.048 and 1.41% (at 450 nm), 966 respectively (Figure S13c,d). 967

To demonstrate the optoelectronic application of our newly 968 synthesized graphenic semiconductor, we employed C<sub>3</sub>N<sub>5</sub> as 969 the electron transport layer (ETL) in MAPbBr<sub>3</sub> based 970 perovskite solar cells and obtained a good result. Carbon 971 based materials have frequently been used as hole transport 972 layers (HTLs) or hole collection electrodes in MAPbBr<sub>3</sub> based 973 solar cells, but have almost never been used (effectively) as 974 ETLs to boost the open circuit photovoltage. Using C<sub>3</sub>N<sub>5</sub> as 975 the ETL and with no optimization of any kind, we measured a 976  $V_{\rm oc}$  of 1.3 V,  $J_{\rm sc}$  of 7.5 mA cm<sup>-2</sup> and a FF (fill factor) of 0.4 to 977 obtain a power conversion efficiency (PCE) of 4.2% (Figures 978 S15 and S16 in Supporting Information). Some context is 979 needed to appreciate the significance of the aforementioned 980 result. Methylammonium lead bromide (MAPbBr<sub>3</sub>) is a halide 981 perovskite with an electronic bandgap of 2.23 eV, which has 982 two major advantages for solar cell applications in comparison 983 to the more commonly used methylammonium lead iodide 984  $(MAPbI_3)$ . In theory, it enables the construction of much 985

Table 4. Photovoltaic Performance of HPSCs Made with Bare  $PbX_2$ , 4 wt % g- $C_3N_4$  and  $C_3N_5$  in  $PbX_2$  Solution under AM1.5 G Solar Simulated Light

		$V_{\rm oc}$ (V)	$J_{\rm sc}~({\rm mA/cm}^2)$	FF	PCE (%)
C <sub>3</sub> N <sub>5</sub>	maximum	1.065	22.870	0.685	16.686
	average	$1.026 \pm 0.043$	$22.560 \pm 1.039$	$0.654 \pm 0.044$	$15.142 \pm 1.442$
g-C <sub>3</sub> N <sub>4</sub>	maximum	1.030	21.573	0.691	15.344
	average	$0.984 \pm 0.042$	$21.204 \pm 0.565$	$0.670 \pm 0.017$	$13.981 \pm 0.949$
bare	maximum	1.040	20.344	0.660	13.959
	average	$1.041 \pm 0.035$	$20.394 \pm 0.200$	$0.647 \pm 0.020$	$13.713 \pm 0.245$



**Figure 13.** (a) Raman spectrum of pristine 4NBT (black), DMAB (yellow) and comparison of SERS spectra of plasmon-exciton coinduced surface catalytic reaction of 4NBT to DMAB on AgNC (purple), AgNC/g- $C_3N_4$  (blue) and AgNC/ $C_3N_5$  (red) under 532 nm laser irradiation at 1.0 mW power and 60 s accumulation time and SERS spectra as a function of laser power for plasmon-exciton coinduced surface catalytic transformation of 4NBT to DMAB on (b) AgNC/ $C_3N_5$  (c) AgNC/g- $C_3N_4$  and (d) AgNC. The gradual lightening of color as a function of laser power represents the transformation of 4NBT to DMAB.

 $_{986}$  higher  $V_{\rm oc}$  solar cells that can be used to power electrocatalytic 987 and electrochemical reactions and second, MAPbBr3 is known to have superior ambient stability (less moisture sensitivity) 988 and operational stability (due to the absence of phase 989 transitions and enhanced thermal stability at a high working 990 temperature) compared to MAPbI<sub>3</sub>.<sup>69</sup> However, until recently, 991 most works in this area failed to achieve the expected high  $V_{\rm oc}$ 992 value, and the typical  $V_{\rm oc}$  values obtained using were in the 993 994 range 0.90–1.16 V.<sup>70</sup> The use of carbon based charge transport 995 layers has enabled a dramatic improvement in the performance 996 of MAPbBr<sub>3</sub> based photovoltaic devices by generating photovoltages in excess of 1.3 V (as high as 1.6 V) without <sup>997</sup> suffering a corresponding penalty in the short circuit current <sup>998</sup>  $(J_{sc})$ . The first such report was by Wu et al.<sup>71</sup> wherein indene- <sup>999</sup> C60 bisadduct (ICBA) was used as the acceptor in conjunction <sup>1000</sup> with MAPbBr<sub>3</sub> to realize a high  $V_{oc}$  perovskite solar cell. <sup>1001</sup> Shortly thereafter, Li et al. used carbon nanotubes as an <sup>1002</sup> efficient hole collector for MAPbBr<sub>3</sub> solar cells and achieved a <sup>1003</sup>  $V_{oc}$  of 1.4 V.<sup>72</sup> MAPbBr<sub>3</sub> sandwiched between modified <sup>1004</sup> PEDOT:PSS (hole transport layer) and PC<sub>61</sub>BM (electron <sup>1005</sup> transport layer) resulted in a solar cell with a  $V_{oc}$  of 1.52 V<sup>73</sup> <sup>1006</sup> while a graphitic carbon anode (with no hole transport layer) <sup>1007</sup> 1008 and TiO<sub>2</sub> electron transport layer were used by Liang et al. to 1009 realize a MAPbBr<sub>3</sub> solar cell with a  $V_{oc}$  as high as 1.57 V.<sup>74</sup> The origin of the poor  $V_{oc}$  values was poorly understood for 1010 1011 a long time. Even now, there are two distinct explanations: one 1012 based on active layer material quality issues and another based 1013 on high interfacial recombination. For instance, vapor 1014 deposited MAPbBr<sub>3</sub> films were found to generate high  $V_{oc}$ 1015 values in comparison with solution-deposited films, which was 1016 attributed to the superior morphology and grain size in the 1017 vapor deposited films, and supported the explanation based 1018 invoking material quality.<sup>75</sup> The second explanation was 1019 supported by the observation of high  $V_{\rm oc}$  values when hole 1020 transport layers with deep HOMO levels were used, indicating 1021 that the separation of the electron- and hole- quasi-Fermi levels 1022 at the charge extraction interfaces was the controlling <sup>1023</sup> mechanism determining  $V_{oc}$ .<sup>76</sup> Our examination of MAPbBr<sub>3</sub> 1024 solar cells using C<sub>3</sub>N<sub>5</sub> as the ETL provides a way to reconcile 1025 the above explanations. On the one hand, the high CB position 1026 of C<sub>3</sub>N<sub>5</sub> is better aligned with the CB of MAPbBr<sub>3</sub>, and enables 1027 an optimal value for the electron quasi-Fermi level at the 1028 perovskite $-C_3N_5$  interface. On the other hand, the low dark 1029 current observed using  $C_3N_5$  ETL in comparison to both TiO<sub>2</sub> 1030 and g-C<sub>3</sub>N<sub>4</sub> ETLs (Figure S17 in Supporting Information) 1031 indicates suppression of trap-mediated hopping through 1032 MAPbBr<sub>3</sub> due to the insertion of C<sub>3</sub>N<sub>5</sub> as a midgap state-1033 free barrier layer, thus enabling the circumventing of active 1034 layer material quality issues. In summary, it is noteworthy that 1035 an unoptimized ETL made with a brand new semiconductor 1036 ( $C_3N_5$ ) that was cast into films from a particulate suspension, 1037 generated a  $V_{\rm oc}$  value of 1.3 V, higher than that generated by 1038 TiO<sub>2</sub> and g-C<sub>3</sub>N<sub>4</sub> ETLs.

The photovoltaic performance of halide perovskite solar cells 1039 1040 is highly dependent on grain size and defects free lattice states 1041 and presence of small numbers of defects and trap sites have a 1042 detrimental effect. The trap assisted recombinations can be 1043 minimized by passivating perovskite layer with graphenic 1044 materials due to their high carrier mobility and surface area 1045 materials, which can efficiently capture charge and improve 1046 transportation behavior resulting in better photoconversion 1047 efficiency.<sup>77</sup> Further, incorporation of graphenic semiconduc-1048 tors with perovskite precursor provide crystallization surface, 1049 which helps in increasing of grain size and minimize defects 1050 density at grain boundaries. The increased conjugation in  $C_3N_5$ 1051 should lead to electron-rich conductive surface with high 1052 charge carrier density and better carrier mobility than g-C<sub>3</sub>N<sub>4</sub>. 1053 To verify this assumption, we have blended MA<sub>x</sub>FA<sub>1-x</sub>Pb-1054 (I<sub>0.85</sub>Br<sub>0.15</sub>)<sub>3</sub> based perovskite with different wt % of C<sub>3</sub>N<sub>5</sub> and 1055 g- $C_3N_4$ . Under optimized conditions, 4 wt % doping of g- $C_3N_4$ 1056 and  $C_3N_5$  with respect to PbX<sub>2</sub> was found best performing and 1057 C<sub>3</sub>N<sub>5</sub> outperformed over g-C<sub>3</sub>N<sub>4</sub> and bare PbX<sub>2</sub> based solar 1058 cell architecture attributed to better charge separation in more 1059 conjugated C<sub>3</sub>N<sub>5</sub> scaffold and reduced trap sites.

f12

1060 Figure 12 shows the J-V curves of the best performing solar 1061 cells devices based on undoped and doped perovskite layers 1062 while the photovoltaic performance of solar cells is 1063 summarized in Table 4. Solar cells made with a compact 1064 undoped perovskite solar cell yielded a short circuit current 1065 density ( $J_{sc}$ ) of about 20.344 mA/cm<sup>2</sup>, an open circuit voltage 1066 ( $V_{oc}$ ) of 1.04 V and fill factor (FF) of about 66% resulting in 1067 the overall power conversion efficiency (PCE) of about 1068 13.959%. While, perovskite solar cell made with g-C<sub>3</sub>N<sub>4</sub>-1069 doped perovskite layer show a  $J_{sc}$  of 21.573 mA/cm<sup>2</sup>,  $V_{oc}$  of 1070 1.03 V and fill factor of about 69.1% and corresponding PCE of about 15.344%. C<sub>3</sub>N<sub>5</sub>-doped perovskite solar cells displayed 1071 a PCE value of 16.689% resulting from  $V_{oc}$  of 1.065 V,  $J_{sc}$  of 1072 22.87 mA/cm<sup>2</sup> and FF of 68.5%.

Capacitance–voltage measurement on fabricated devices 1074 with doped/undoped perovskite layer was measured at 10 kHz 1075 frequency in dark to determine bulk properties such as doping 1076 density ( $N_{\rm D}$ ) and energy equilibrium at the contacts, which is 1077 related to the flat-band potential ( $V_{\rm fb}$ ).<sup>78</sup> Mott–Schottky plots 1078 for the devices made with doped and undoped perovskite layer 1079 are shown in Figure 13.

$$\frac{1}{C_{\rm sc}^2} = \frac{2}{e\varepsilon_0 \varepsilon_{\rm r} N_{\rm D}} \left\{ \left( V - V_{\rm FB} \right) - \frac{kT}{e} \right\}$$
(8) 1081

$$N_{\rm D} = \frac{2}{e\varepsilon_0 \varepsilon_{\rm r} n} \tag{9}_{1082}$$

 $V_{\rm fb}$  and  $N_{\rm D}$  were calculated by using eq 8 and eq 9 1083 respectively, where  $C_{\rm sc}$  is the space-charge capacitance (i.e., 1084 film capacitance) per unit area;  $\varepsilon_{\rm r}$  is the dielectric constant of 1085 the material,  $\varepsilon_0$  is the vacuum permittivity, k is Boltzmann 1086 constant, T is temperature in Kelvin, e is the electron charge 1087 and V is the applied potential. The measured  $V_{\rm fb}$  of bare 1088 undoped, g-C<sub>3</sub>N<sub>4</sub>-doped and C<sub>3</sub>N<sub>5</sub>-doped perovskite solar cell 1089 was found to be 1.12, 1.08, and 1.15 V respectively, while 1090 carrier concentration of the respective devices was found to be 1091  $1.74 \times 10^{16}$ ,  $1.96 \times 10^{16}$  and  $1.36 \times 10^{16}$  cm<sup>-3</sup>. This proves 1092 that doping perovskite layer with C<sub>3</sub>N<sub>5</sub> significantly improves 1093 the charge transport in the device compared to the undoped 1094 and g-C<sub>3</sub>N<sub>4</sub>-doped devices. 1095

To explore the charge transport characteristics, hole only 1096 devices with the architecture of FTO/PEDOT:PSS/Perov- 1097 skite/Spiro-oMeTAD/Au was measured by the space charge 1098 limited current (SSLC) model described by the following 1099 equation: 1100

$$J = \frac{9}{8L^3} \epsilon_0 \epsilon_r \mu V^2 \tag{10}_{1101}$$

Where  $\epsilon_0$ ,  $\epsilon_r$ ,  $\mu$  and *L* are permittivity of the free space, relative 1102 permittivity of the perovskite, carrier mobility in the perovskite 1103 layer and thickness of perovskite layer, respectively. The hole 1104 mobility in pure perovskite was found to be 2.55 × 10<sup>-3</sup> cm<sup>2</sup>/ 1105 sS, while that of g-C<sub>3</sub>N<sub>4</sub>- and C<sub>3</sub>N<sub>5</sub>-doped perovskite was 1106 found to be 3.28 × 10<sup>-3</sup> cm<sup>2</sup>/(V s) and 4.33 × 10<sup>-3</sup> cm<sup>2</sup>/(V s), 1107 respectively (Figure S19).

To get insight into the charge transfer properties of 1109 perovskite solar cells based on undoped and doped perovskite 1110 layer, solid-state impedance spectroscopy measurements in the 1111 frequency range from 0.1 Hz to 1 MHz at different applied bias 1112 under dark conditions were performed. The resulting Nyquist 1113 plots were fitted with the circuit shown in inset of Figure 12c, 1114 where  $R_s$  is series resistance,  $R_{rec}$  and C represent the resistance 1115 and capacitance at the interface between the active layer and 1116 charge transport layer and Q is a constant phase element 1117 (CPE) with coefficient N. The resulting recombination 1118 resistance of different solar cells obtained after fitting the 1119 Nyquist plot observed from the low-frequency region at 1120 different voltages is shown in Figure 12d-i. The C<sub>3</sub>N<sub>5</sub>-doped 1121 device showed a higher value of R<sub>rec</sub> compared to the g-C<sub>3</sub>N<sub>4</sub>- 1122 doped and undoped devices. As the electron and hole 1123 transporting layers for all kind of devices are same, the 1124 difference in  $R_{\rm rec}$  is mostly governed by the change in the 1125 interfacial property of perovskite layer induced by doping with 1126



**Figure 14.** (a and b) Topographical AFM images (ai, bi) and Surface potential maps of  $g-C_3N_4$  and  $C_3N_5$  samples deposited on FTO (aii and bii) without light, (aiii and biii) with 635 nm lased, (aiv and biv) with 520 nm laser, (av and bv) with 450 nm laser in sequence of top to bottom and surface potential distribution of (c)  $g-C_3N_4$  and (d)  $C_3N_5$  samples deposited on FTO under dark conditions, under illumination with 635, 520 and 450 nm laser.

<sup>1127</sup> C<sub>3</sub>N<sub>5</sub> and g-C<sub>3</sub>N<sub>4</sub>. Interfacial recombination is inversely <sup>1128</sup> proportional to the recombination resistance; therefore, it <sup>1129</sup> can be concluded that the interfacial charge recombination in <sup>1130</sup> perovskite solar cells significantly gets suppressed by doping <sup>1131</sup> with MHP, while it increases by doping with g-C<sub>3</sub>N<sub>4</sub> resulting <sup>1132</sup> in an improved  $V_{\rm oc}$  in C<sub>3</sub>N<sub>5</sub> based device followed by the <sup>1133</sup> undoped and doped devices.

<sup>1134</sup> The low band gap and extended  $\pi$  conjugation of  $C_3N_5$ <sup>1135</sup> makes it an excellent candidate to harvest solar light to drive <sup>1136</sup> visible light induced catalytic reaction. Recently, plasmonic <sup>1137</sup> materials capable of generating hot electrons, coupled with <sup>1138</sup> graphenic materials, have shown wide potential in plasmon-<sup>1139</sup> exciton coinduced surface catalytic reactions.<sup>79</sup> The plasmon-<sup>1140</sup> exciton coupling for codriven chemical reactions can be <sup>1141</sup> measured by surface enhanced Raman spectroscopy (SERS).<sup>80</sup> <sup>1142</sup> To probe the viability  $C_3N_5$  for promoting chemical reaction <sup>1143</sup> on its surface, the transformation of 4NBT (4-nitrobenzene-<sup>1144</sup> thiol) to DMAB (4,4'-dimercaptoazobenzene) was chosen as model reaction, while silver nanocubes (AgNC)<sup>81</sup> were used as 1145 plasmonic material. The comparative SERS spectra of NBT 1146 adsorbed on bare AgNC, and AgNC decorated on  $g-C_3N_4$  mW 1147 and C<sub>3</sub>N<sub>5</sub> using 532 nm laser and 1 mW laser power are 1148 presented in Figure 13a. Normal Raman spectra of the pristine 1149 4NBT powder show three main Raman signals at 1101, 1332 1150 and 1576 cm<sup>-1</sup> assigned to S—C stretch, NO<sub>2</sub> vibration and 1151 C=C stretch, respectively.<sup>82</sup> After irradiating with 532 nm 1152 laser with a 1 mW power intensity, the N-O vibration was 1153 decreased and new peaks at 1142 (C—N stretch), 1389 and 1154 1438 (N=N stretch) cm<sup>-1</sup> corresponded to DMAB a<sub>g</sub> modes 1155 emerged demonstrating conversion of 4NBT to DMAB.<sup>83</sup> For 1156 bare AgNC the drop in 4NBT peak was not significant, which 1157 showed inefficient surface-plasmon-to-hot-electron conversion 1158 to promote plasmon-driven chemical reaction. The AgNC/g- 1159 C<sub>3</sub>N<sub>4</sub> showed a slight lowering of 4NBT peak intensity and rise 1160 in DMAB peaks; however, the peak was not disappeared 1161 suggesting incomplete transformation at lower laser power. 1162 1163 While for AgNC/C<sub>3</sub>N<sub>5</sub> the N—O vibration peak was 1164 completely disappeared at 1.0 mW laser power. Further, we 1165 tested laser power dependent SERS spectra on NBT adsorbed 1166 samples, which demonstrate complete disappearance of 4NBT 1167 peaks for  $Ag/C_3N_5$  even at 0.7 mW, while bare Ag and AgNC/ 1168 g-C<sub>3</sub>N<sub>4</sub> system could not achieve complete degradation even at 1169 10 mW laser power (Figure 13b-d). Magnified SERS spectra 1170 of Ag/C<sub>3</sub>N<sub>5</sub> in the 1270–1470 cm<sup>-1</sup> region showed a gradual 1171 decrease in N-O vibration peak as a function of laser power 1172 AgNC and completely disappeared at 1.0 mW (Figure S20). A 1173 sluggish transformation rate was observed for AgNC/g-C<sub>3</sub>N<sub>4</sub> 1174 and AgNC as evident from the increase in 4NBT peak at 1332 1175 cm<sup>-1</sup> along with DMAB peak at 1389 and 1438 cm<sup>-1</sup> as a 1176 function of laser intensity. The excellent conversion efficiency 1177 of AgNC/C<sub>3</sub>N<sub>5</sub> assembly was attributed due to better 1178 plasmon-to-electron conversion efficiency on conjugated 1179 C<sub>3</sub>N<sub>5</sub>'s surface, which lead to high-density hot electrons to 1180 facilitate high catalytic conversion.<sup>7</sup>

We performed thermogravimetric analysis (TGA) analysis of 1181 1182 g-C<sub>3</sub>N<sub>4</sub> samples to determine the thermal stability of materials 1183 (Figure S21). The TGA thermogram of  $g-C_3N_4$  shows two 1184 weight loss regimes in the range of 60-150 °C and 500-740 1185 °C (Figure S21a). The first small weight loss ( $\sim 6\%$ ) in the 1186 range of 60-150 °C was due to loss of surface adsorbed water 1187 molecules. The second major weight loss started from 550 °C, 1188 showed slow weight loss (~8%) up to 635 °C due to loss of 1189 NH<sub>2</sub> and condensation of heptazine units followed by almost 1190 ~70% sharp weight loss in the range of 635-740 °C due to 1191 degradation of heptazine moieties.<sup>84</sup> Following that, a steady 1192 weight loss was observed up to 900 °C due to the removal of 1193 residual carbon material. For C<sub>3</sub>N<sub>5</sub>, an initial small weight loss 1194 of 6% in the range of 60–150 °C was attributed due to loss of 1195 surface adsorbed and intercalated water (Figure S21b). A 1196 second steady weight loss ( $\sim$ 34%) observed in the temperature 1197 range of 420-630 °C was assigned to loss of bridging azo 1198 nitrogens (-N=N-) and edge decorated  $-NH_2$  nitrogens. 1199 The absence of any sharp weight loss for azo nitrogens 1200 demonstrates that azo nitrogens were not localized but present 1201 in a cross-linked heptazine network. Previous reports on azo-1202 linked polymer also demonstrated excellent thermal stability of 1203 such polymers due to the formation of a rigid structure.<sup>85</sup> 1204 Further, the observed weight loss value was in close agreement 1205 with expected weight loss value for azo nitrogen (33.5%) 1206 calculated by considering removal of three azo nitrogens 1207 (-N=N- shared by two heptazine) from azo-bridged C<sub>6</sub>N<sub>10</sub> 1208 unit, leaving behind C<sub>6</sub>N<sub>7</sub> heptazine unit. These results further 1209 validated the presence of azo nitrogens in C<sub>3</sub>N<sub>5</sub> polymer. 1210 Approximately 38% sharp weight loss in 630-720 °C region 1211 was assigned to degradation of heptazine ring system followed 1212 by slow weight loss up to 900 °C for residual carbon. Further, 1213 to investigate the nature of the product formed at high 1214 temperature, we annealed the sample in a closed evacuated 1215 quartz tube at 800 °C for 4 h. The orange product turned black 1216 and stuck to the wall of the tubes. Raman analysis of the 1217 product showed specific D, G band along with the 2D band 1218 and demonstrate its transformation into N-doped graphene/ 1219 carbon (Figure S22). Previous reports also demonstrate the 1220 transformation of carbon nitride based materials/nitrogenous 1221 precursors into N-graphene/N-carbon at higher temperatures. To understand charge carrier dynamics and recombination 1222  ${}^{1223}$  mechanisms in  $C_3N_5{}\!\!\!\!$  , the surface potential changes of the 1224 samples under dark and under laser illumination at different 1225 wavelengths, were measured using Kelvin Probe Force

Microscopy (KPFM) as illustrated in Figure 14. The surface 1226 fl4 topographical AFM image of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> thin films 1227 deposited on bare FTO reveals an average roughness of 20.4 1228 and 19 nm, respectively (Figure 14ai,bi). Figure 14aii-v and 1229 bii-v displays the surface potential map of g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> 1230 samples under dark conditions, 635, 520 and 450 nm, 1231 respectively. The FTO was grounded and behaves as an 1232 electron sink for photogenerated charges, leaving holes behind. 1233 The surface potential map under dark for both g-C<sub>3</sub>N<sub>4</sub> and 1234 C<sub>3</sub>N<sub>5</sub> shows even distribution of charge all over the surface of 1235 samples, (Figure 14aii,bii). After illumination with 635 nm 1236 laser the contrast of blue spots (positive potential shift) in the 1237 surface potential map was increased for both g-C<sub>3</sub>N<sub>4</sub> and 1238  $C_3N_5$ ; however, this change was much intense for  $C_3N_5$ . Under 1239 520 nm light, the density of blue spots was slightly higher for g- 1240 C<sub>3</sub>N<sub>4</sub> than C<sub>3</sub>N<sub>5</sub>, which drastically increased under 450 nm 1241 illumination (Figure 14a (aiv,v) and Figure 14b (biv,v). These 1242 observations demonstrate that highest charge generation and 1243 accumulation on the surface was at 450 nm for g-C<sub>3</sub>N<sub>4</sub> and at 1244 635 nm for C<sub>3</sub>N<sub>5</sub> while remaining moderate for both at 520 1245 nm. Further, values of surface potential measured by KPFM 1246 under dark condition were found to be +156 and +45 mV for 1247 g-C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>5</sub> respectively, which agreed well with the 1248 increased electron density on C<sub>3</sub>N<sub>5</sub> than g-C<sub>3</sub>N<sub>4</sub> due to 1249 contribution of charge from azo motif to heptazine ring system 1250 via extended orbital overlap (Figure 14c,d). The high surface 1251 negative charge of C3N5 was also confirmed by Z-potential 1252 measurements (Figure S8). After illumination with 450 nm 1253 light, the surface potential was negatively shifted reaching 1254 maximum +40 mV for  $g-C_3N_4$  and +25 mV for  $C_3N_5$ . Higher 1255 change in contact potential difference (CPD) or SP, i.e. 102 1256 mV, for g-C<sub>3</sub>N<sub>4</sub> was observed due to good absorption at 450 1257 nm for generation of electron-hole pairs and accumulation of 1258 negative charge on the sample surface. The broad surface 1259 potential peaks and significantly larger CPD shift for g-C<sub>3</sub>N<sub>4</sub> 1260 were attributed possibly due to the longer lifetime (as 1261 confirmed by TRPL, Figure 8a) of g-C<sub>3</sub>N<sub>4</sub> charge carriers 1262 resulting into delayed recombination of accumulated charge. 1263 Under 520 nm illumination, the surface potential values for g- 1264  $C_3N_4$  and  $C_3N_5$  were measured to be 123 and 8 mV, while the 1265 change in SP was found to be 33 and 37 mV, respectively. For 1266 g-C<sub>3</sub>N<sub>4</sub>, relatively small CPD shifting at 520 nm can be 1267 explained due to its limited absorption at 520 nm wavelength 1268 generating fewer numbers of excitons, while in C<sub>3</sub>N<sub>5</sub> most of 1269 the photogenerated charge get recombined due to faster 1270 recombination rate. Interestingly, C3N5 showed an unusually 1271 high SP shift (77 mV) at 635 nm, while g-C<sub>3</sub>N<sub>4</sub> showed an 1272 explicitly small CPD shift (30 mV). The exceptional high SP 1273 shift at 635 nm demonstrated azo motif plays a certain role in 1274 charge carrier generation and stabilization at a longer 1275 wavelength. Azo-bridged aromatic compounds are well- 1276 known for their visible light absorption due to the presence 1277 of azo chromophore (-N=N-) in conjugation with aromatic 1278 units. The  $n-\pi^*$  transition corresponding to azo nitrogen 1279 nonbonding orbital to the  $\pi^*$  orbital of conjugated nitrogens in 1280 azo moiety occurs at low energy giving visible light 1281 absorption.<sup>86</sup> In C<sub>3</sub>N<sub>5</sub> where electron withdrawing heptazine 1282 units  $(C_6H_7)$  were bridged together with azo bonds, these low 1283 energy transition can take place at 635 nm resulting into 1284 increase CPD shift at 635 nm. The high surface potential of 1285 C<sub>3</sub>N<sub>5</sub> at 635 nm validates its potential to generate excitons at 1286 longer wavelengths. 1287

## 1288 CONCLUSION

1289 We report the synthesis of a modified carbon nitride 1290 framework C<sub>3</sub>N<sub>5</sub> polymer containing exceptionally high N:C 1291 atomic ratio (5:3) melem hydrazine as the monomeric unit. 1292 Extensive characterization of C<sub>3</sub>N<sub>5</sub> with XPS, EELS, NMR 1293 spectroscopy and elemental analysis suggested the presence of 1294 heptazine moiety bridged by azo nitrogens in the C<sub>3</sub>N<sub>5</sub> 1295 framework. Because of the overlap between the  $\pi$  orbitals of 1296 azo-bridged units and the  $\pi$ -conjugated network of the 1297 heptazine unit, the bandgap of C<sub>3</sub>N<sub>5</sub> material was significantly 1298 reduced which, in turn, enabled optical absorption extended up 1299 to 700 nm and a bandgap of 1.76 eV. The position of the 1300 valence band in C<sub>3</sub>N<sub>5</sub> was raised (+1.04 V vs NHE) in 1301 comparison to g-C<sub>3</sub>N<sub>4</sub> (+1.80 V vs NHE) and C<sub>3</sub>N<sub>5</sub> displayed 1302 excellent photosensitizing behavior to sensitize TiO<sub>2</sub> at longer 1303 wavelengths (505 nm) to facilitate photoelectrochemical water 1304 splitting. Because of the increased nitrogen content and the 1305 availability of electron-rich basic nitrogen sites, C<sub>3</sub>N<sub>5</sub> materials 1306 displayed astonishing dye adsorption performance for methyl-1307 ene blue removal reaching 90% adsorption-desorption 1308 equilibria within 1 min and complete adsorption-desorption 1309 equilibria within 10 min. In conjunction with Ag nanocubes, 1310 C<sub>3</sub>N<sub>5</sub> displayed excellent photocatalytic activity for the 1311 plasmon-exciton (plexciton) codriven reduction of 4-nitro-1312 benzenethiol to 4,4'-dimercaptoazobenzene. A prototypical 1313 solar cell device using C3N5 ETL and MAPbBr3 displayed an 1314 improved  $V_{oc}$  of 1.3 V and power conversion efficiency (PCE) 1315 of 4.2% higher than g-C<sub>3</sub>N<sub>4</sub> ETL. C<sub>3</sub>N<sub>5</sub> blended with 1316 MA<sub>x</sub>FA<sub>1-x</sub>Pb( $I_{0.85}Br_{0.15}$ )<sub>3</sub> perovskite active layer achieved a 1317 photoconversion efficiency (PCE) as high as 16.7%.

## 1318 ASSOCIATED CONTENT

#### 1319 **Supporting Information**

1320 The Supporting Information is available free of charge on the 1321 ACS Publications website at DOI: 10.1021/jacs.9b00144.

Experimental details, chemical structures, Supporting 1322 Figures (Figure S1-S22), XPS, ssNMR, Raman, electro-1323 chemical characterization (Mott-Schottky, EIS), PL, 1324 fluorescence lifetime imaging,  $\zeta$ -potential, EELS, TGA, 1325 photoelectrochemical water splitting results (under AM 1326 1.5G irradiation, LEDs PCE, IPCE, APCE, i-t curve), 1327 solar cell results (J-V curves, action spectra) and 1328 plexitonic performance (SERS spectra) (PDF) 1329

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### 1339 Notes

1340 The authors declare no competing financial interest.

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